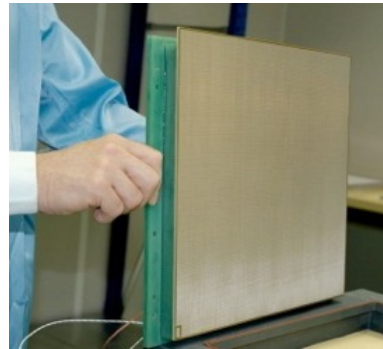
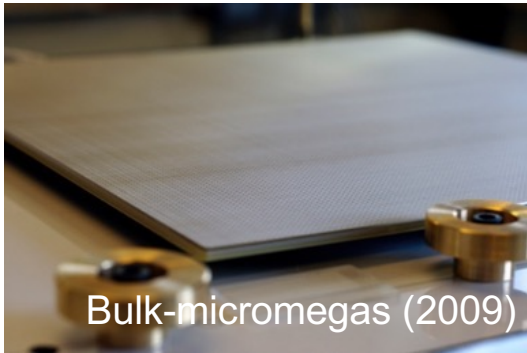




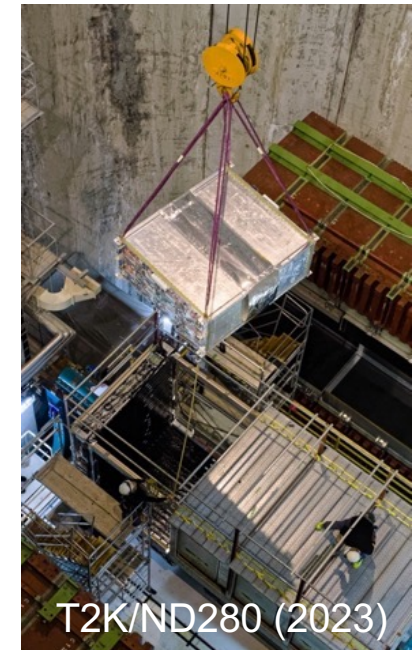
# Production of Encapsulated Resistive Anode Micromegas (ERAM) for the T2K High-Angle TPCs

Alain Delbart, CEA/IRFU - Univ. Paris-Saclay, for the ND280/HA-TPC group

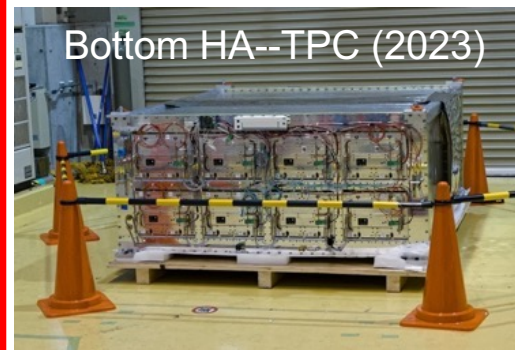
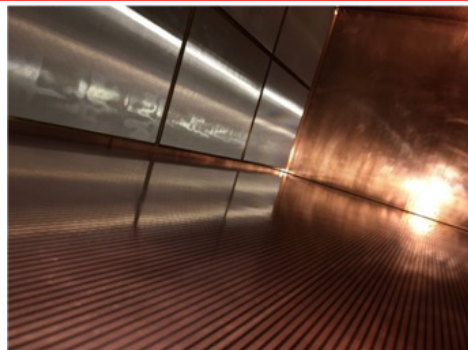
Vertical TPC (2004-) for ND280



ND280 @ JPARC (Japan)

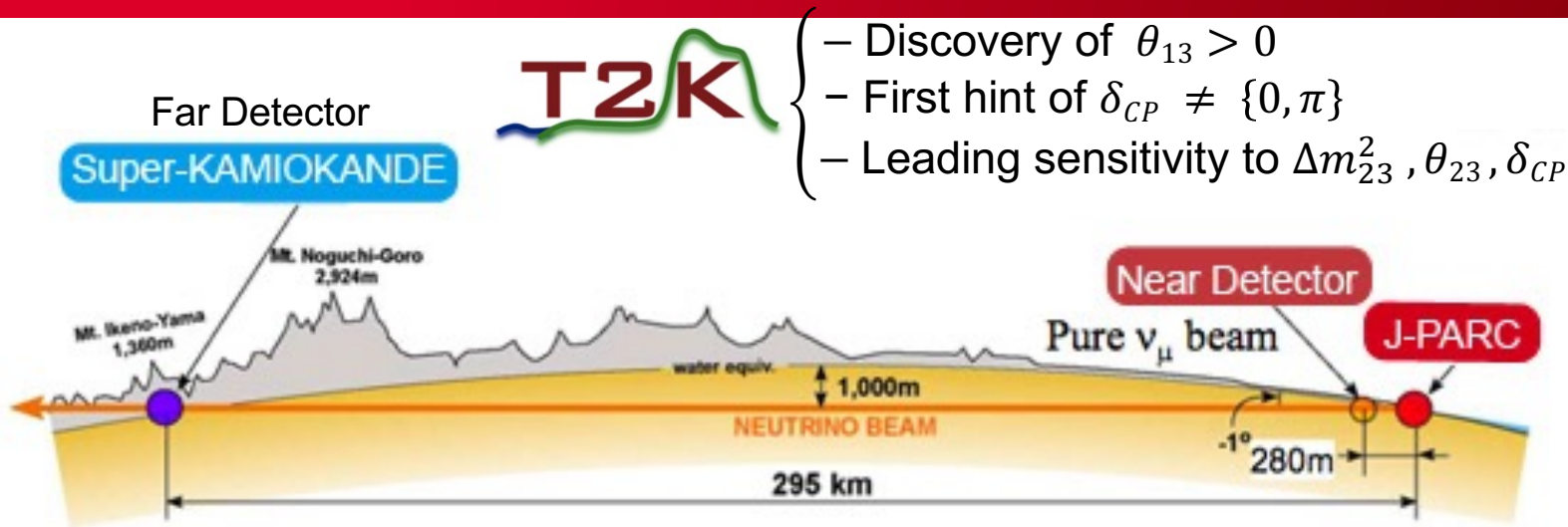


High-Angle TPC (2018-) for ND280 upgrade





# THE T2K EXPERIMENT: TOKAI TO KAMIOKA FROM T2K TO T2K-II AND T2-HK

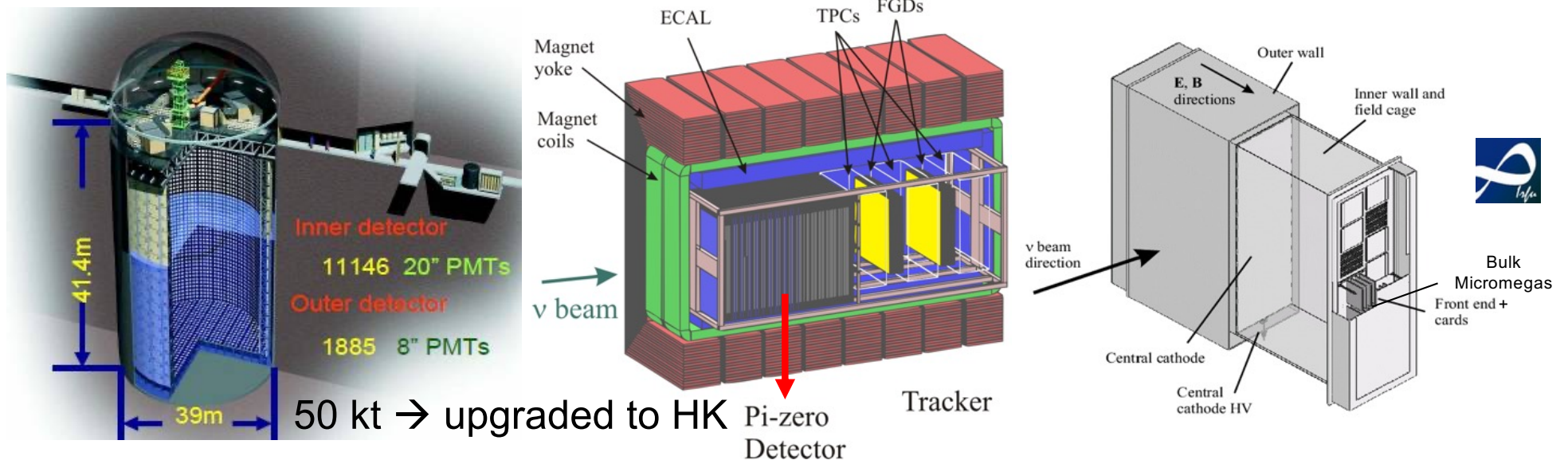


- Discovery of  $\theta_{13} > 0$
- First hint of  $\delta_{CP} \neq \{0, \pi\}$
- Leading sensitivity to  $\Delta m_{23}^2, \theta_{23}, \delta_{CP}$

Volume 580 Issue 7803, 16 April 2020



Upgraded beam power : 560kW (2023) with gradual increase to 1.3 MW goal for HyperK



ND280 upgrade goal : reducing systematic uncertainties on beam characterization ...

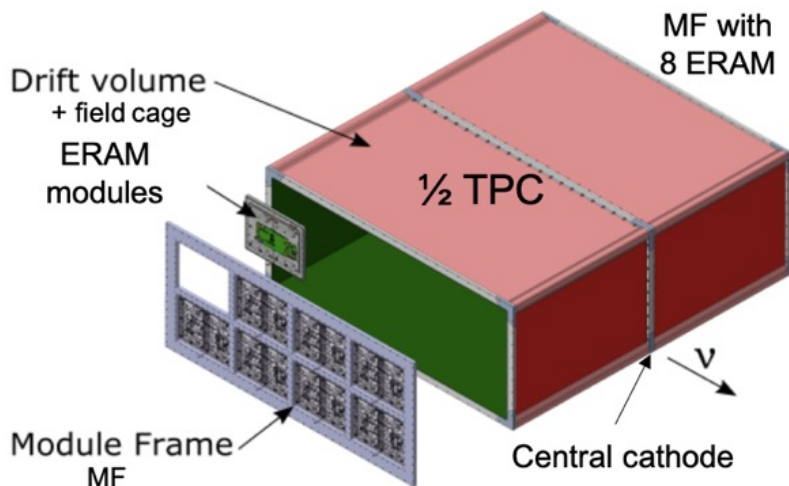
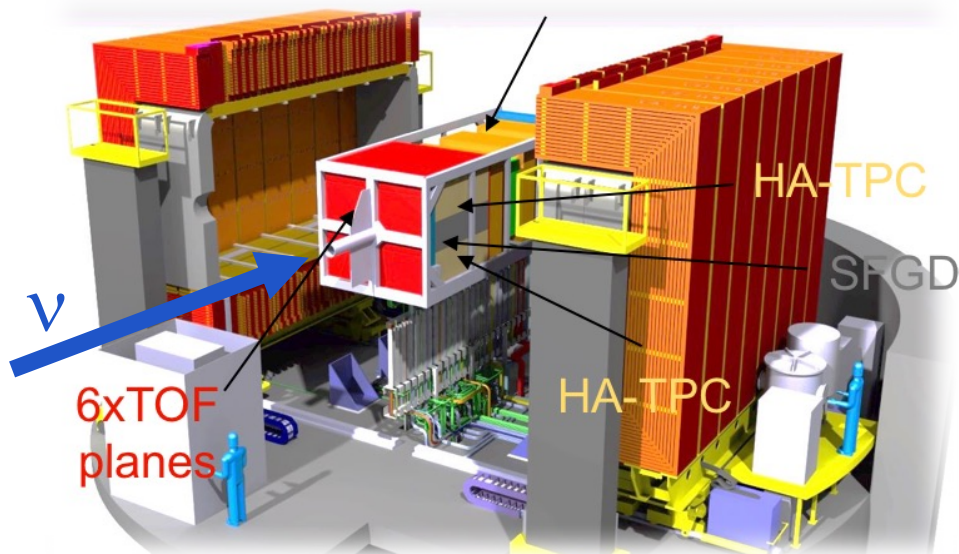




# THE DEVELOPMENT OF THE UPGRADED NEAR DETECTOR OF T2K THE HA-TPC (2018-2024)

... with 2 new TPCs with better final state muons acceptance from new SFGD target and from downstream events

2009 TPCs (x3) + T2K Gas system by CERN (mixing, filtering, gas properties monitoring)



Parameter	HA-TPC	v-TPC
Overall x × y × z (m)	2.0 × 0.8 × 1.8	0.85 × 2.2 × 1.8
Drift distance (cm)	90	
Magnetic Field (T)	0.2	
Electric field (V/cm)	275	
Gas Ar-CF <sub>4</sub> -iC <sub>4</sub> H <sub>10</sub> (%)	95 - 3 - 2	
Drift Velocity cm/μs	7.8	
Transverse diffusion (μm/√cm)	265	
Micromegas gain	1000	
Micromegas dim. z × y (mm)	340 × 420	340 × 360
Pad z × y (mm)	10 × 11	7 × 10
N pads	36864	124272
el. noise (ENC)	800	
S/N	100	
Sampling frequency (MHz)	25	
N time samples	511	
Channel density (nb. / cm <sup>2</sup> )	0.9	1.4

## ND280 upgrade TPCs achievements

- First experiment to use ERAM detectors
- Performances similar or better than v-TPCs with ~1/3 less electronics channel density
- New innovative field cage design for high acceptance and dead volume reduction

May 2022 : first scale 1 1/2 field cage exhibits a non-linear V-I behaviour  
 → Leakage current flow through the wall structure

extra increasing non linearly with voltage

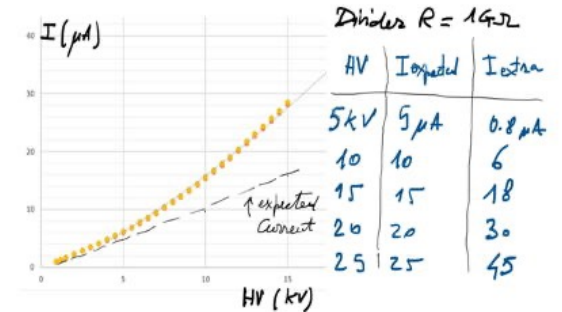
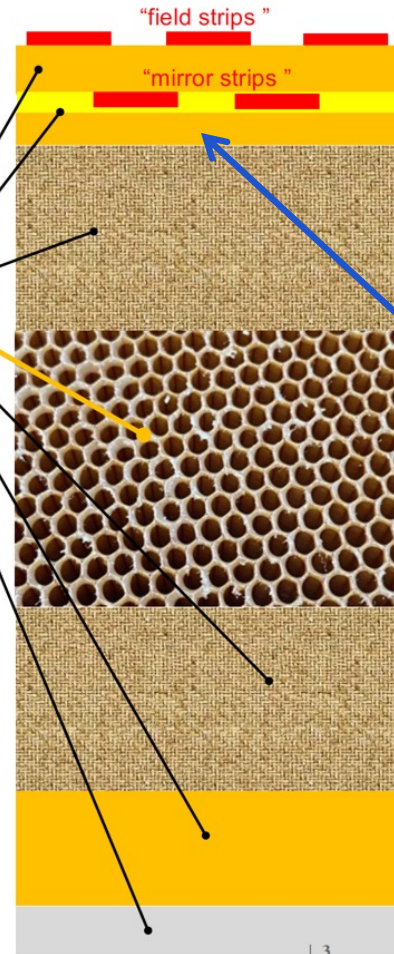
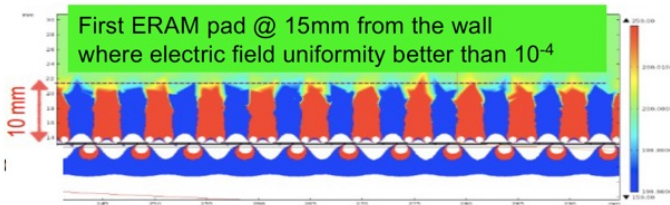
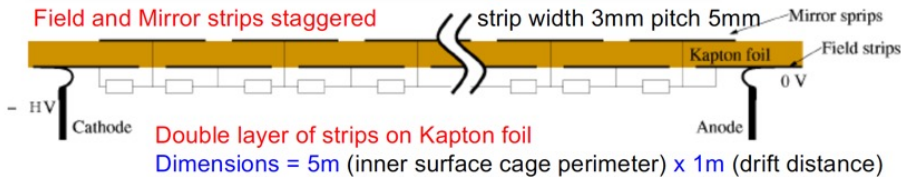
## Field Cage – layers

See G.C. talk at  
 15th Pisa Meeting on Advanced Detectors  
 La Biodola, Isola d'Elba, May 22-28, 2022

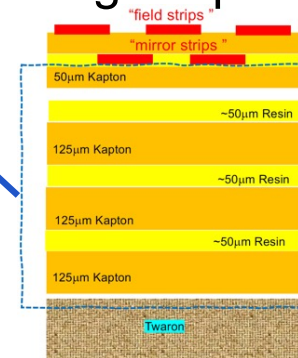
Material	Thickness
Cu Strips on Kapton foil (electrodes)	Cu 17μm / Kapton 50μm / Cu 17μm
“Coverlay” (strip insulation / protection)	Glue 20μm / Kapton 25μm
Aramid Fiber Fabric (Twaron™)	2mm
Aramide HoneyComb panel	35mm
Aramid Fiber Fabric (Twaron™)	2mm
Kapton foil (insulation)	125μm
Aluminum foil (external shield)	50μm
Total	~ 4 cm / ~ 2% radiation length

Note: V-TPC ~ 12cm / ~ 3.4% radiation length

## Electric field shaping



## New design & procedures



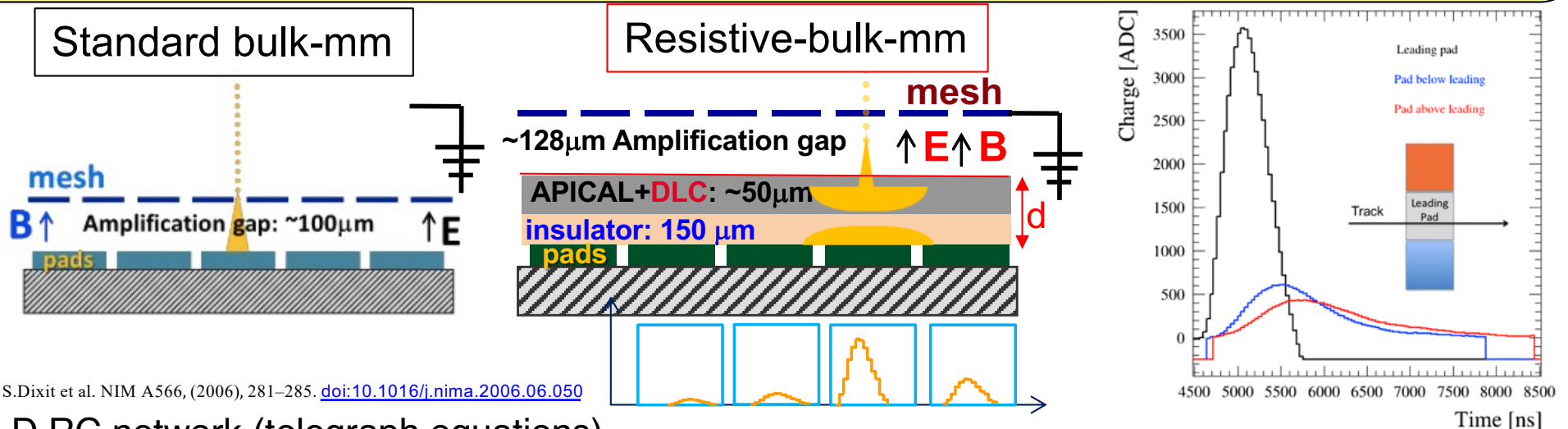
- Keep same raw materials
- Avoid resin contamination
- Add thick insulator below strip foil (O(10 TΩ) @ 10 kV) :
  - a 50 μm kapton foil pressed on strip foil at MPGD workshop
  - 3x125 μm Kapton foils wrapped at NEXUS

Ref: G. Collazuol (INFN/Padova)



### Choice of the Resistive foil technology for the HA-TPC micromegas readout

- Charge spreading which should enable keeping the  $\sim 600 \mu\text{m}$  spatial resolution with larger pads and improves it at short drift distance  $\rightarrow$  less electronic channels, cost reduction
- ASIC spark protection no longer needed  $\rightarrow$  more compact FEE, maximize HA-TPC acceptance
- Encapsulated mesh @ GND + insulating layer  $\rightarrow$  potentially lower track distortions & better S/N



M. S. Dixit et al. NIM A566, (2006), 281–285. doi:10.1016/j.nima.2006.06.050

2-D RC network (telegraph equations)

$$\rho(r, t) = \frac{RC}{2t} \exp\left[-\frac{r^2 RC}{4t}\right]$$

R- surface resistivity  
C- capacitance/unit area



Gaussian spreading as a function of time with :

$$\sigma_r = \sqrt{\frac{2t}{RC}} \quad \left\{ \begin{array}{l} t \approx \text{shaping time (few 100 ns)} \\ RC_{[ns/mm^2]} = 10^3 \epsilon_0 \epsilon_r \frac{R_{[M\Omega/\blacksquare]}}{d_{[\mu m]}} \end{array} \right.$$

$\epsilon_r$  [APICAL]  $\sim 3,3$  and  $\epsilon_r$  [glue]  $\sim 4,8$

For  $\sim 11 \times 10 \text{ mm}^2$  pads, DLC R is chosen  $\sim 0.5 \text{ M}\Omega/\blacksquare$  and the glue thickness  $\sim 150 \mu\text{m}$ ,  $RC_{\text{design}} \sim 100 \text{ ns/mm}^2$

ILC/TPC R&D :  $7 \times 3 \text{ mm}^2$  / DLC R  $\sim 2.5 \text{ Mohm}$  for an  $RC \sim 750 \text{ ns/mm}^2$   $\sigma_r < 2 \text{ mm}$



# ERAM DEVELOPMENT

D. Attié et al. NIM A1052, (2023), 164288.  
doi.org/10.1016/j.nima.2023.168248

D. Attié et al. NIM A984, (2020), 163286.  
doi:10.1016/j.nima.2019.163286

D. Attié et al. NIM A1025, (2022), 1661109.  
doi:10.1016/j.nima.2019.166109

Nov. 12  
PRR

Pre-series  
To series production

ILC-TPC heritage

2018

2019

2020

2021

CERN/T9 test beam    DESY test beam

ERAM-01 @ DESY 2021  
½ TPC @ CERN/T10 sept. 2022

	2018 MM0-DLC#	2019 MM1-DLC1 & 2	2020 ERAM-P1 & P2	Production ERAM-xx (ERAM-01-28)
Readout PCB	v-TPC PCB	HA-TPC V1 + ARC FEE	HA-TPC V2 + final FEE V1	HA-TPC V2 + final FEE V2
Size	34 × 36 cm <sup>2</sup>	34 × 42 cm <sup>2</sup>	34 × 42 cm <sup>2</sup>	34 × 42 cm <sup>2</sup>
Pads	48 × 36 cm <sup>2</sup>	32 × 36 cm <sup>2</sup>	32 × 36 cm <sup>2</sup>	32 × 36 cm <sup>2</sup>
Pad size	6,85 × 9,65 mm <sup>2</sup>	10,09 × 11,18 mm <sup>2</sup>	10,09 × 11,18 mm <sup>2</sup>	10,09 × 11,18 mm <sup>2</sup>
Number of pads	1728	1152	1152	1152
DLC resistivity (MΩ/sq.)	~2,5 (original foil) Not meas. on detector ILC/TPC foil	0,32-0,44 (batch#P1 foils) 0,2-0,27 (meas. on detector)	0,28-0,40 (batch#P1 foils) 0,15-0,22 (meas. on detector)	~1 (foils) / ~0.28-0,4 (det.) Top TPC: 1-1.5 (foils) After baking: 0,4-0,55
RC <sub>design</sub> [ns/mm <sup>2</sup> ] RC <sub>data</sub> [ns/mm <sup>2</sup> ]	~260	50 < RC < 70	15 < RC < 23	55 < RC < 78 102 < RC < 145
Insulation layer	200 μm glue + 50 μm APICAL	75 μm glue + 50 μm APICAL	200 μm glue + 50 μm APICAL	150 μm glue + 50 μm APICAL
Expected σ (mm) For 200 ns peaking t For 412 ns peaking t	~1,6 ~2,3	~4 ~5,6	~6 ~8,5	~3,8 ~5,4
dE/dX (measured 1 det.) Extrapol. to 2 detectors	9 to 9.5% (e- & p) <7%	9 to 9.5 % (e-) with 0.2T <7%	Energy resolution @5.9 keV <sup>55</sup> Fe :	Energy resolution @5.9 keV <sup>55</sup> Fe to be measured
Spatial resolution (μm) Beam (Horizontal tracks) cosmics	300 (0T)	MM1-DLC1 200 (0 or 0.2T, 200/400 ns t <sub>p</sub> ) 700 (MM1-DLC2, @370V)	300-350 (ERAM-Px @370V)	@ DESY 07/ 21 380-300 (ERAM-01) for 200ns & 412ns

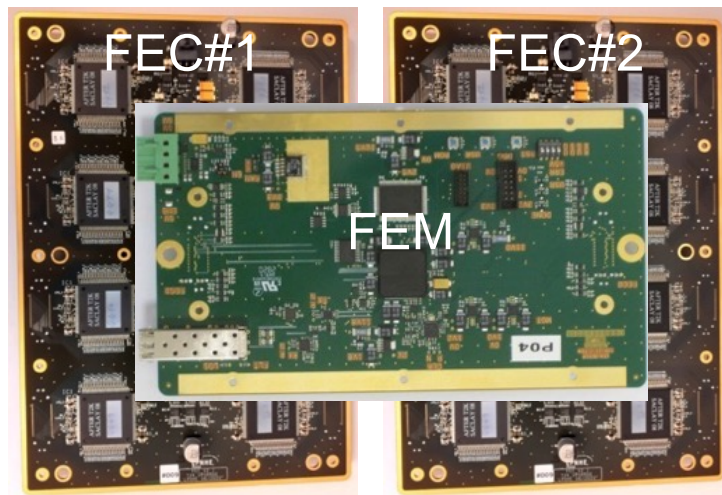


# THE HA-TPC ERAM MODULE

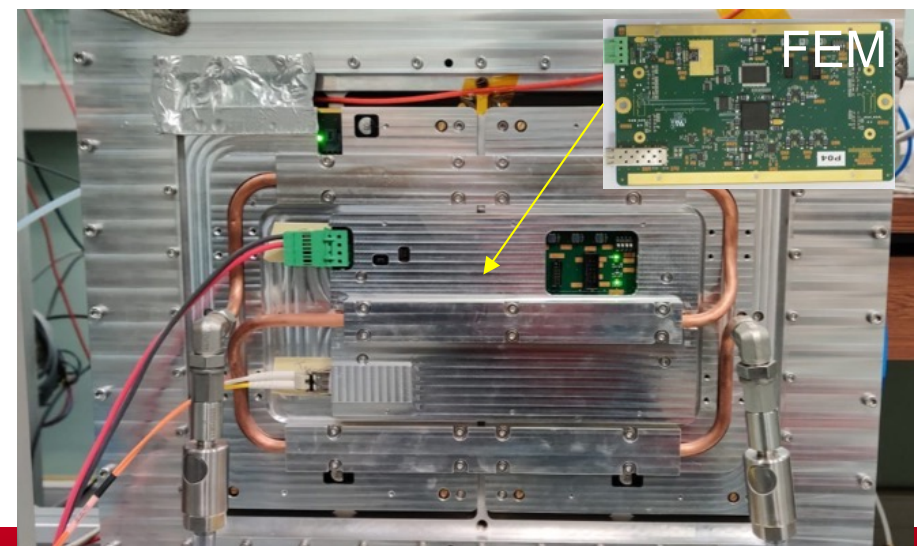
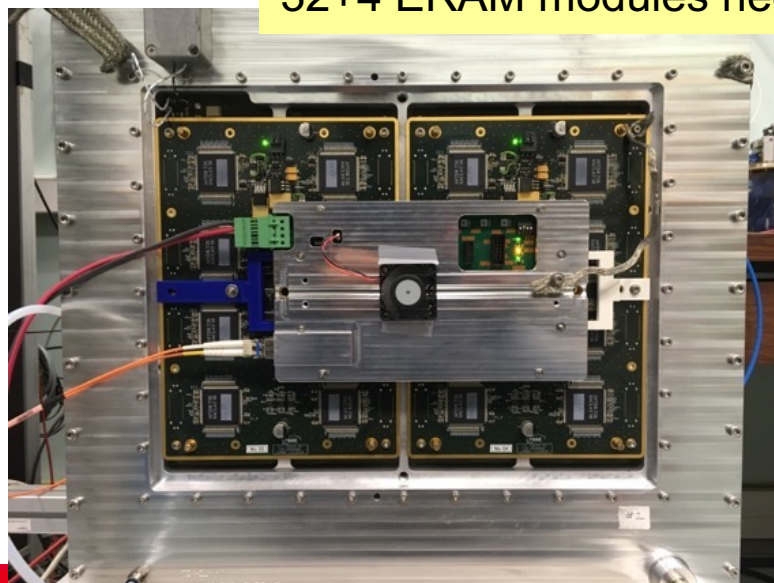
## A COMPACT TPC READOUT SYSTEM

ERAM FEE : 2 x 576 ch. FECs (8xAFTER ASICs)  
+ 1 digital FEM (~500 cm<sup>2</sup> cards)

T2K/ERAM detector (CERN MPGD workshop)



32+4 ERAM modules needed (detector + FEE + cooling mechanicals)

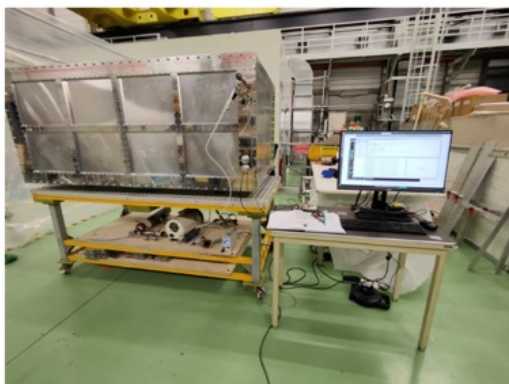






# INTEGRATION OF ERAM DETECTORS IN CLEAN ROOM (~ISO 7-8)

ref: D. Henaff (CEA/IRFU)  
Coordination @ CERN bdg. 182



*Final leak test of FC1 with Helium*



*Last cleaning inside the cage*



*First row of ERAM installed*



*Last ERAM installation*



*Leak test after ERAM installation*

**Field cage  
ready!**

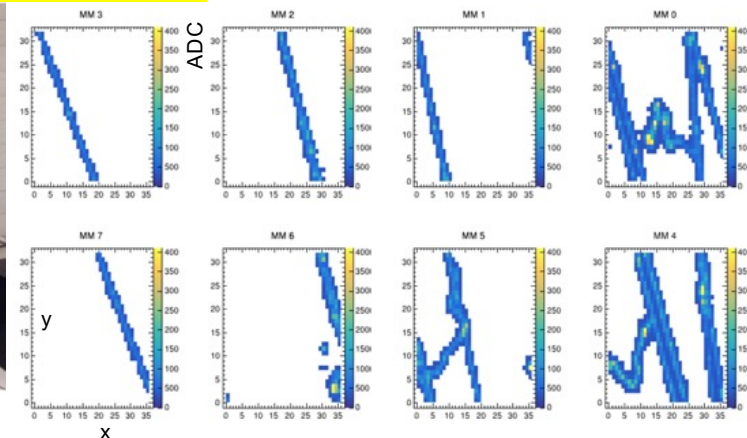
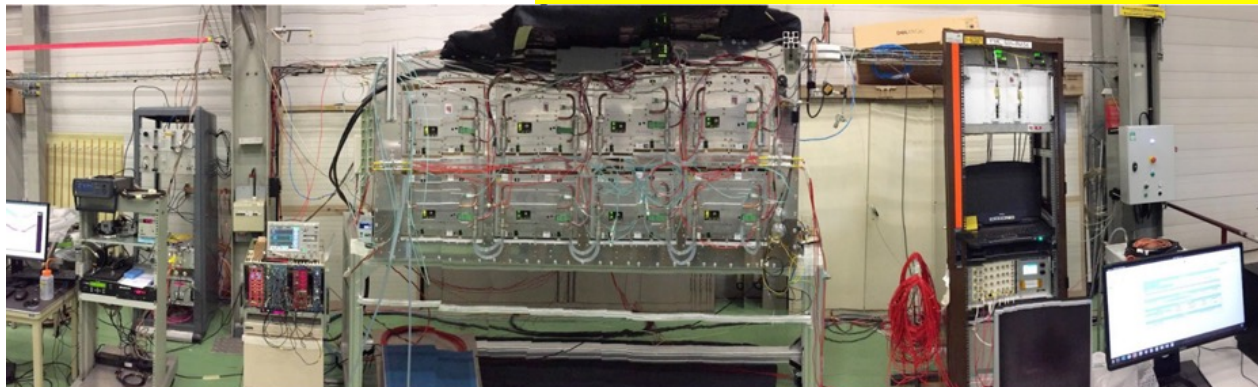




# « BOTTOM » HA-TPC FROM CERN TO JPARC (JAPAN)

Final validation with cosmics at CERN

after 10 TPC vol. exchange



Gas rack:  
Control flow and monitor gas quality (GMC+sensors)

Trigger:  
Readout of the two scintillator panels (1m<sup>2</sup>)

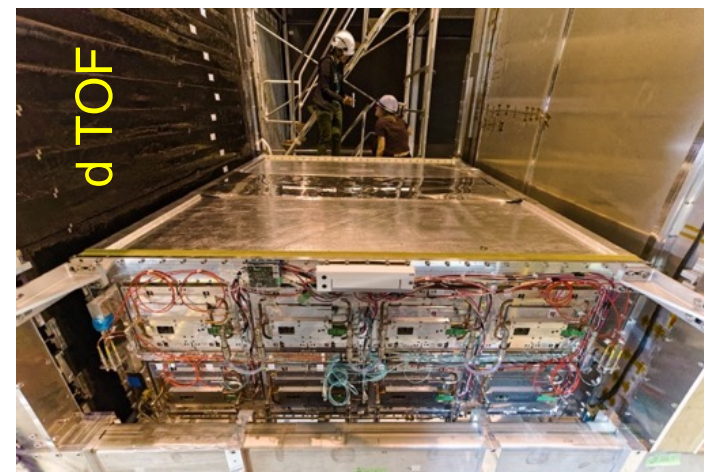
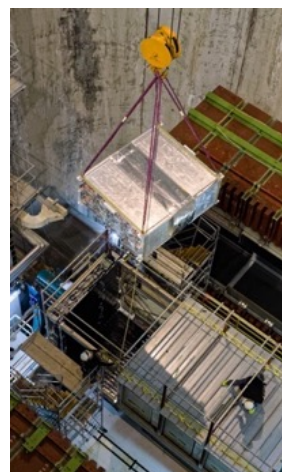
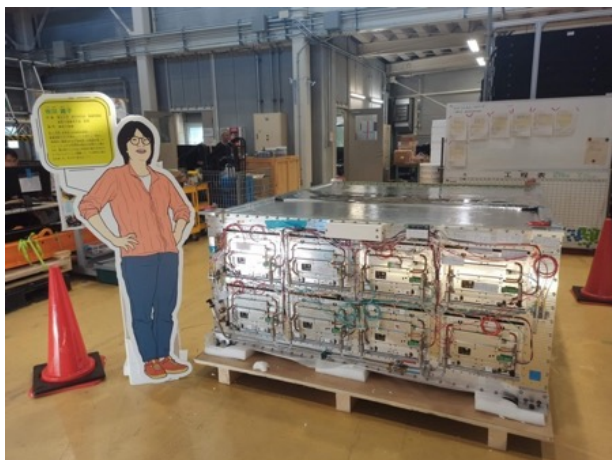
Half HA-TPC:  
27.5kV and 350V on ERAMs

Electronic rack:  
DAQ, ERAM & electronic power supplies

10 ppm O<sub>2</sub>/~300 ppm H<sub>2</sub>O

Integration in ND280 « basket » at JPARC (8 sept 2023)

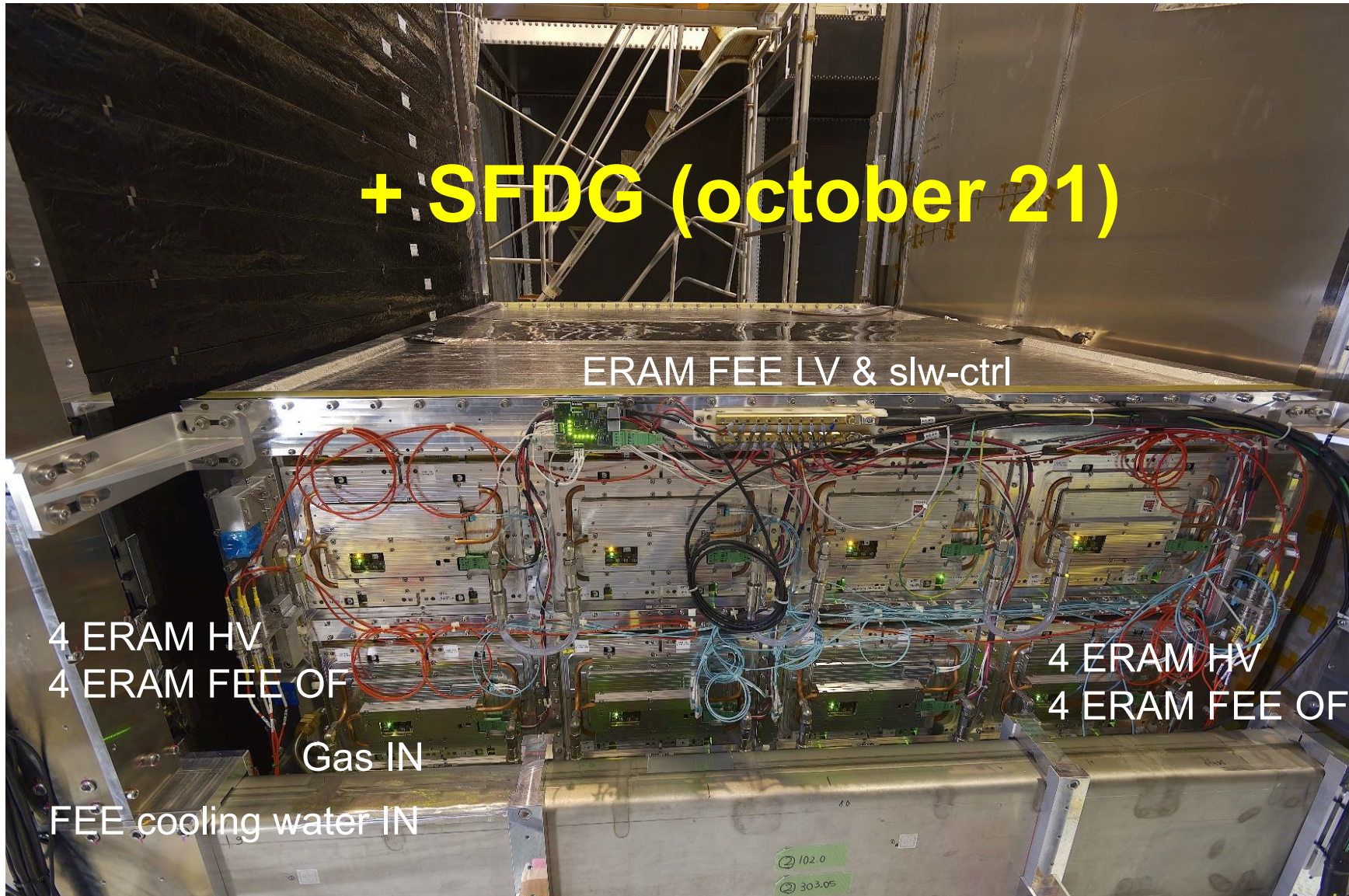
ref: T. Lux (IFAE)







# THE HA-TPC READOUT PLANE IN ND280 BASKET @ JPARC (SEPT 8)



+ SFDG (october 21)

ERAM FEE LV & slw-ctrl

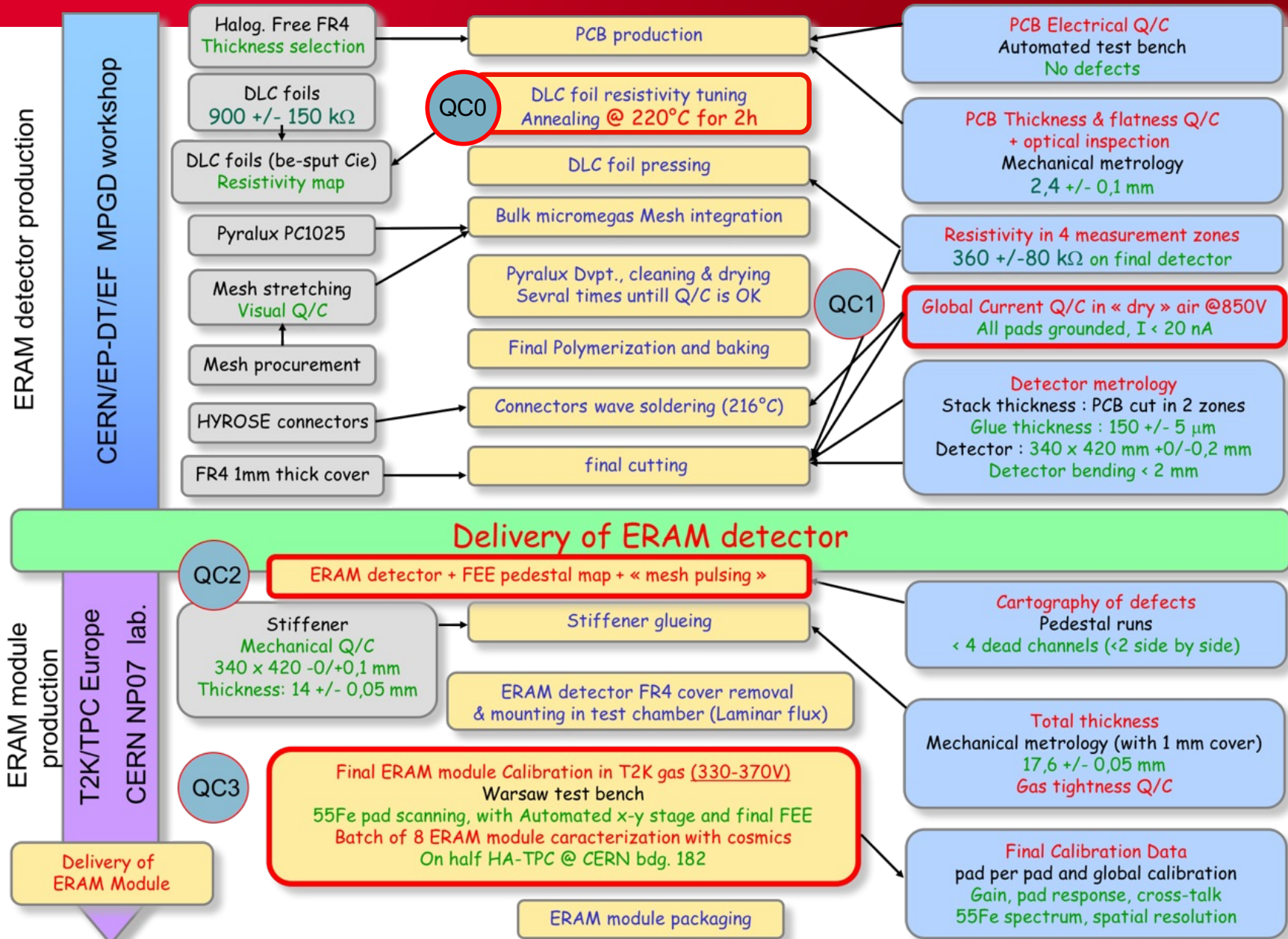
4 ERAM HV  
4 ERAM FEE OF

4 ERAM HV  
4 ERAM FEE OF

Gas IN

FEE cooling water IN







# QC0: DLC RESISTIVITY : FOIL SELECTION



production (batch 1,2,4)

Top. TPC production

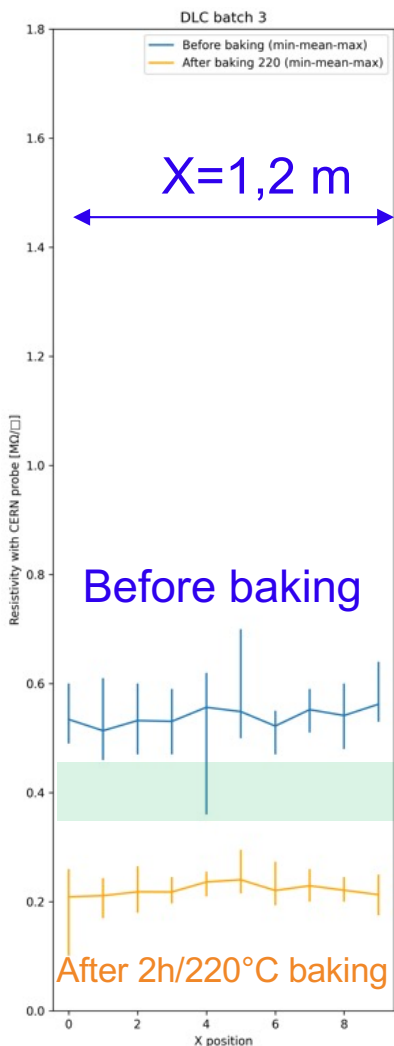
21 ERAM

1/2 RC prototype

Production

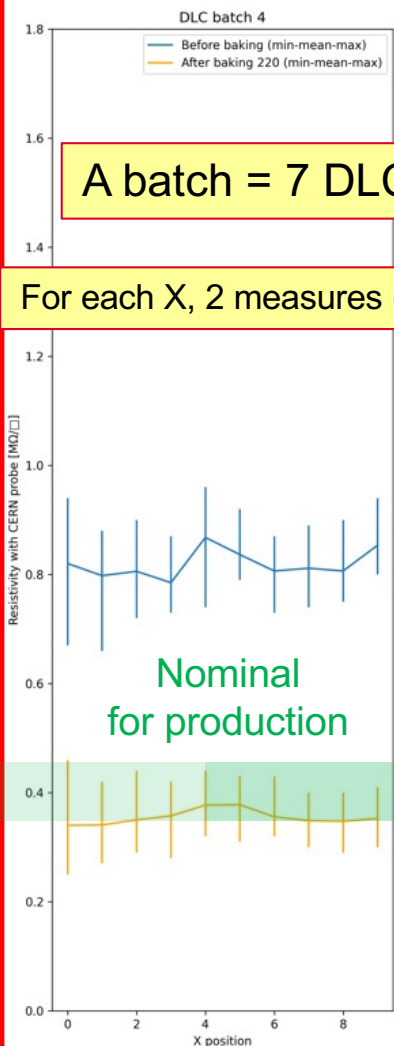
prototype

Restart of production for Top TPC

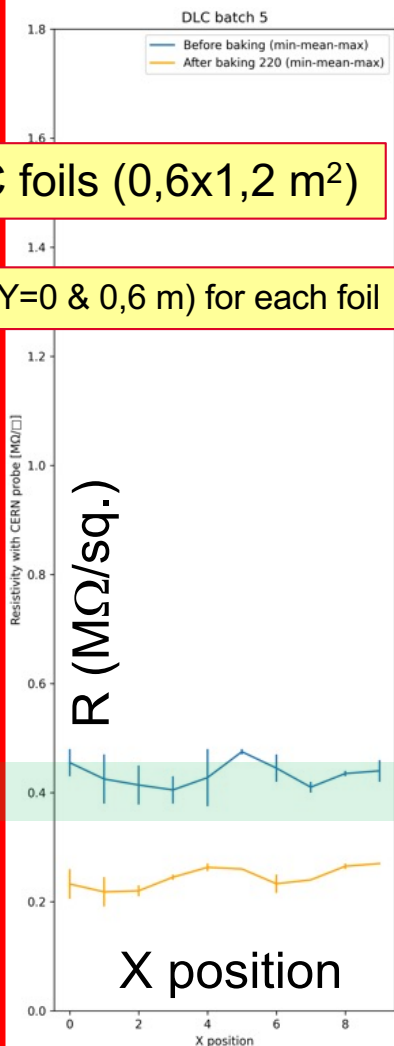


1/2 R, 1/2 RC

→ ERAM-18



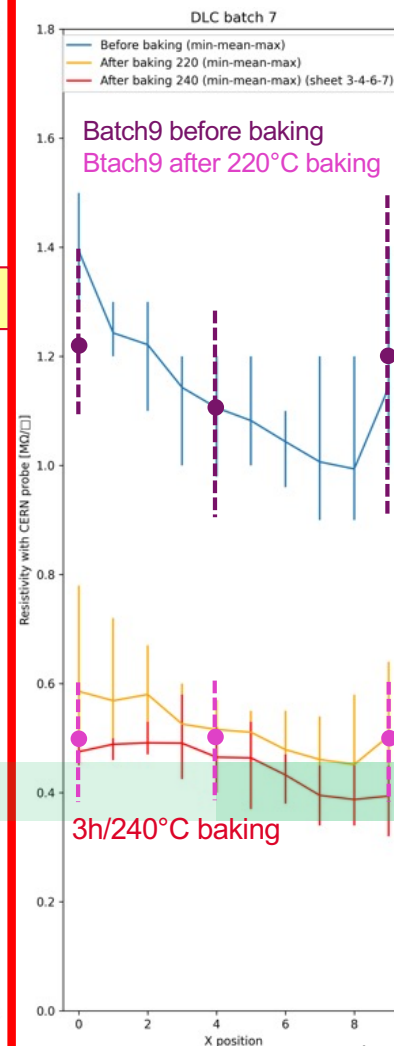
nominal R, RC



1/2 R, 1/2 glue thick.

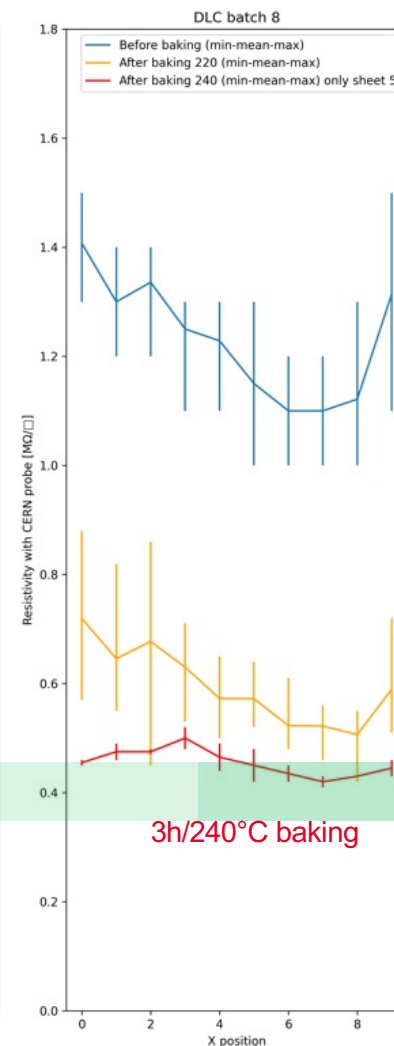
Nominal RC

→ ERAM-29



6 ERAMs with batch 7 (25, 27, 33, 34, 36, 37) : gain gradient & spreading issues

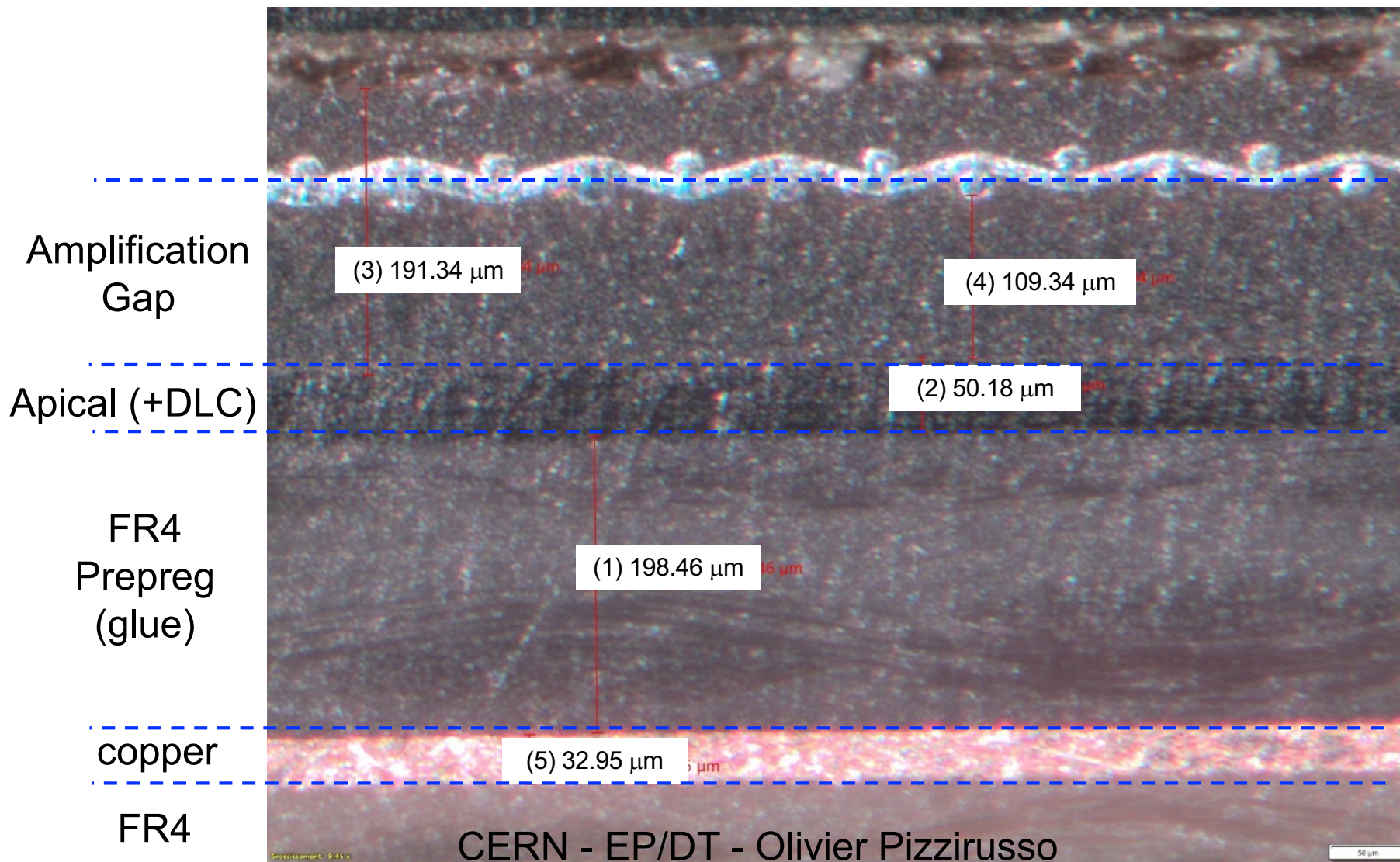
→ 11 last ERAMs done with batch 9 (R~0.5 MΩ/sq.)







# QC0: CONTROL OF GLUE THICKNESS EX: 200 MICRONS GLUE PROTOTYPE

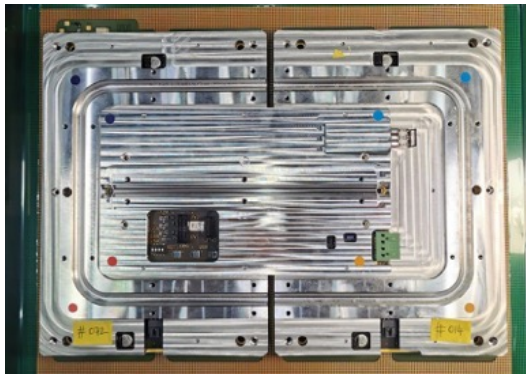




# QC2 : ELECTRONIC MESH PULSING

## DETECTING DEFECTS BEFORE GLUING THE ALUMINUM STIFFENER

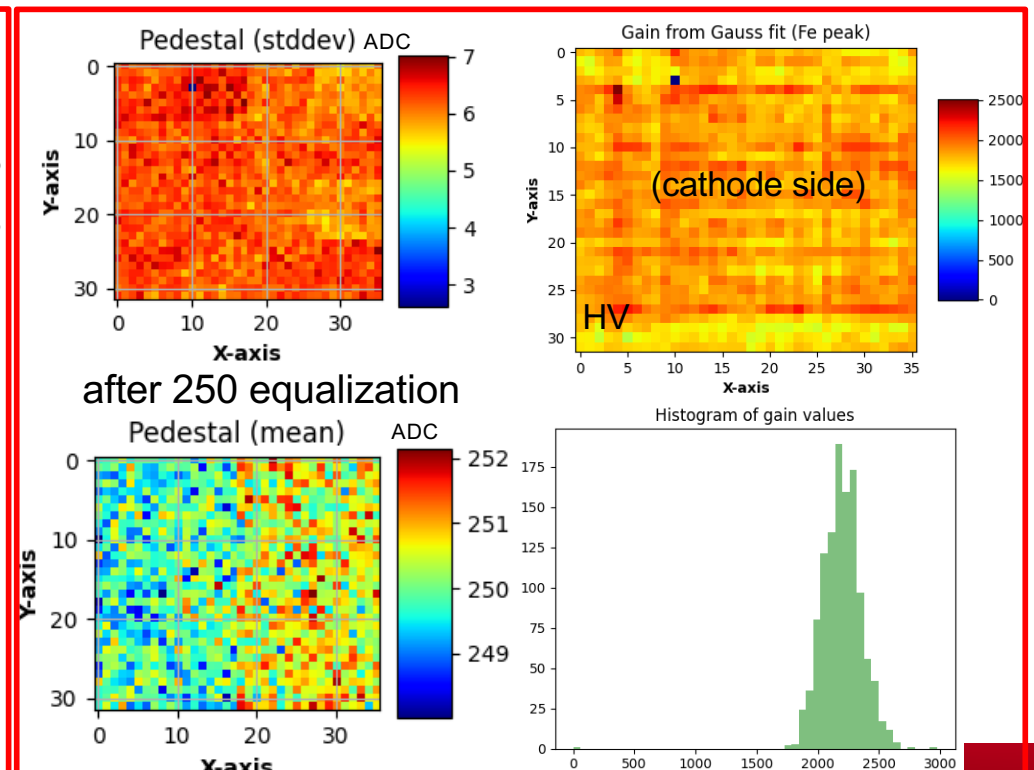
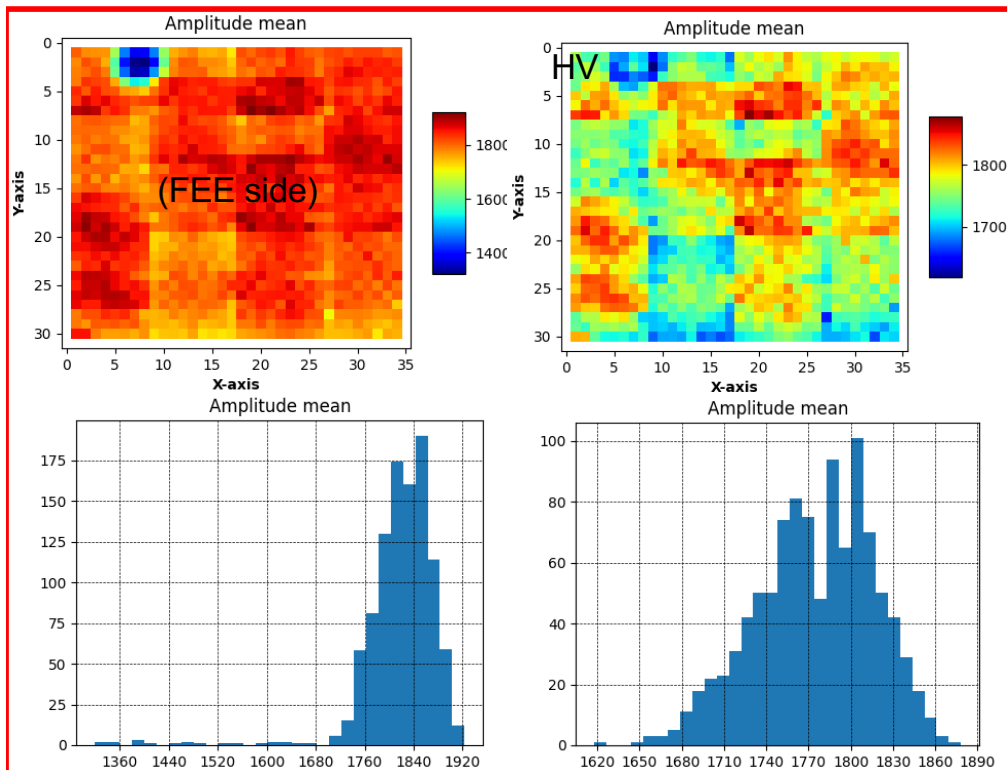
### EXAMPLE OF A DEFECT ON ERAM-20



- ✓ The “mesh-pulsing” is a QC used before & after gluing of the mechanical stiffener to **detect major defects**
- ✓ A 1kHz, 300 mV **square signal** is pulsing the ERAM mesh through a 50  $\Omega$  adapted cable
- ✓ The readout electronics DAQ is triggered with a NIM signal synchronized with the mesh pulsing (~5 mn run).

QC2: mesh pulsing before & after « repair »

QC3: X-ray scan gain

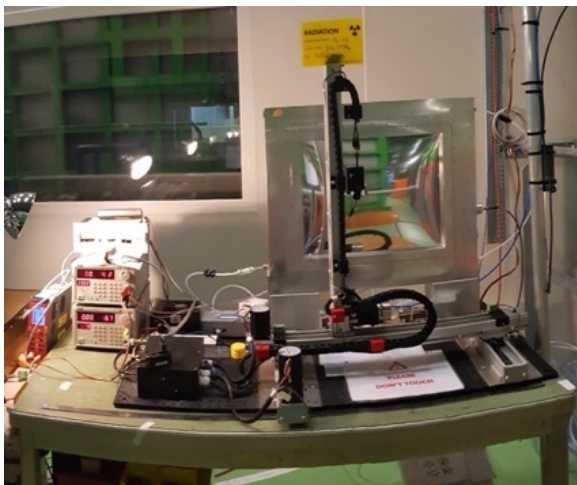




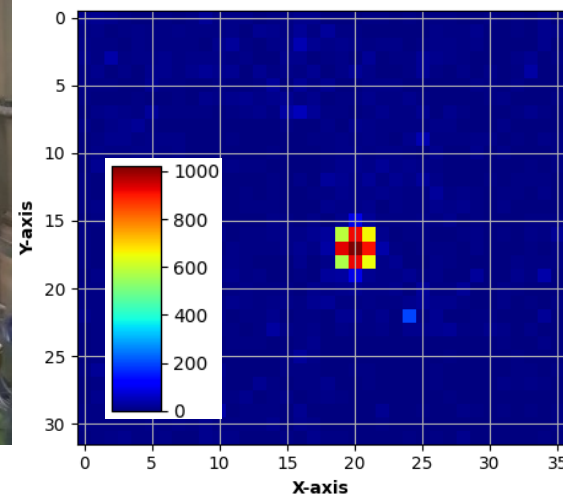


# QC3: FINAL VALIDATION OF A MODULE THE ERAM $^{55}\text{Fe}$ X-RAY TEST BENCH @ CERN

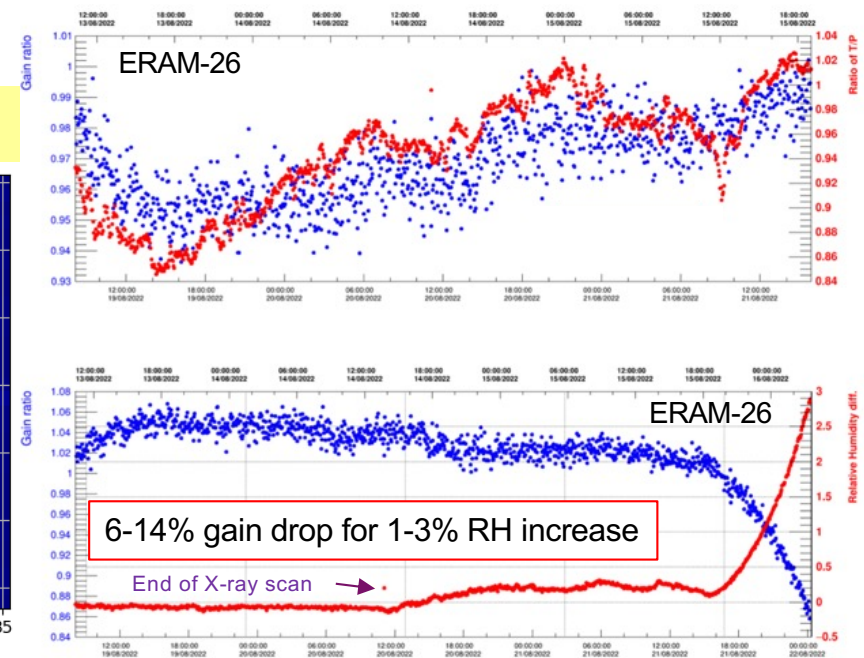
- ✓ Each ERAM is paired with 2 Front-End cards and “calibrated” for the use in the experiment
- ✓ Effective gain (ERAM \* FE) and energy resolution @ 5.9 keV measurement on each pad with ERAM DLC layer at 350 V (nominal HV)
- ✓ The 280 MBq  $^{55}\text{Fe}$  X-ray source is collimated in a  $\Phi 7$  mm spot in the center of each pad
- ✓ The source is moved by an X-Y robot with respect to a reference pad which is “cross-scanned” with the source to locate its center (20 points every 1 mm in X&Y)
- ✓ Gas flow is 14l/h, the scan starts when RH<0.4% and stable, full scan duration 64h (3 mn/pad)
- ✓ Monitoring of “environmental conditions” : Gas composition (supplier certificate),  $T_{\text{amb}}$ ,  $P_{\text{atm}}$ ,  $\Delta p_{\text{chamber}}$ ,  $T_{\text{gas}}$ , Relative Humidity  $\text{RH}_{\text{Gas out}}$
- ✓ HV scan (330 - 360 V) on pad x20/Y17 (gain tuning)
- ✓ Remote shifting with local hardware support



Source spot (gain scan)

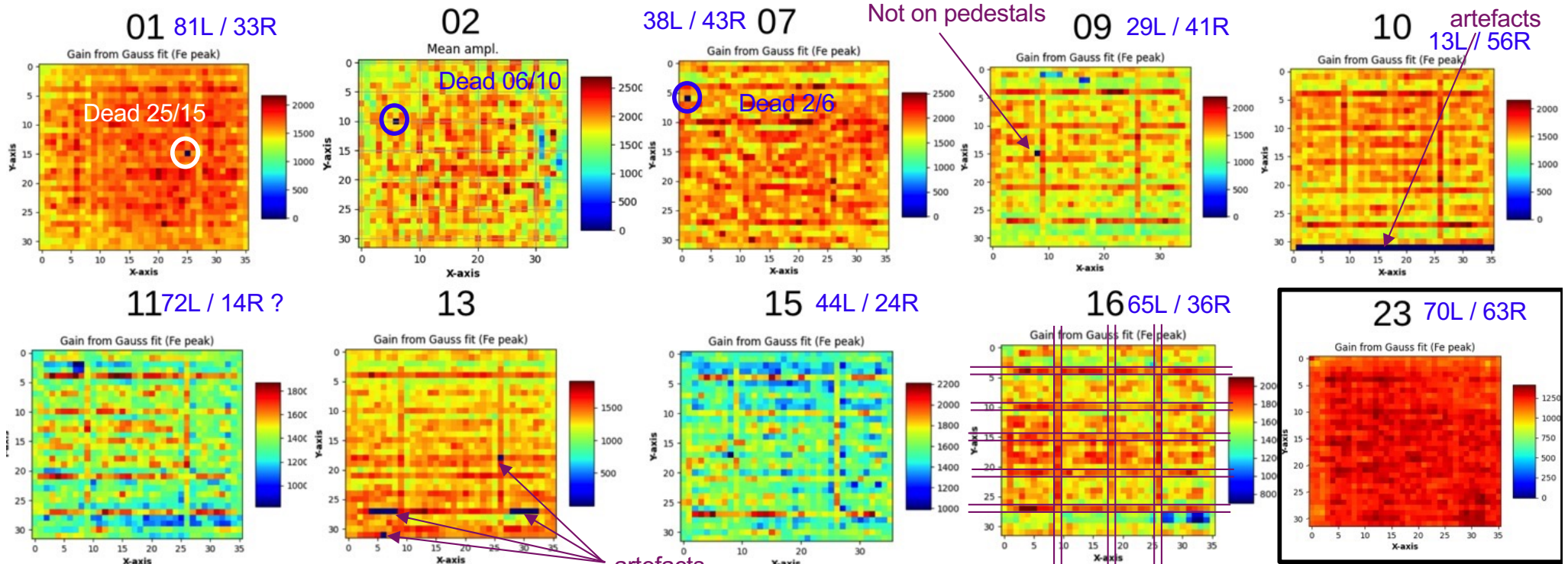


Gain correlation with T/P





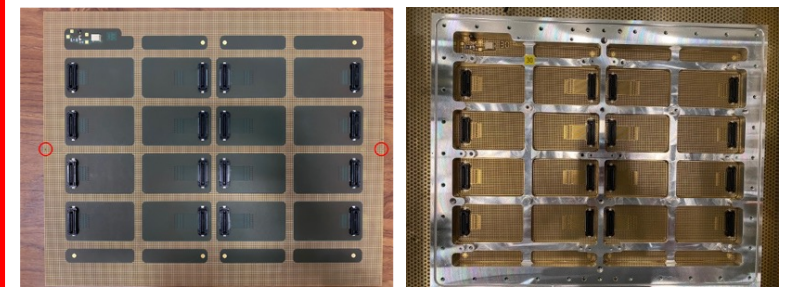
# THE UNEXPECTED EFFECT OF THE ERAM PCB BACKSIDE LAYER DESIGN ON GAIN



Bare FR4 areas on PCB backside = location of Al stiffener ribs gluing

14 82L / 57R + 03, 12, 18 (200 kΩ/sq.)

**ERAMs up to S/N 23 : higher gain below stiffener ribs**  
 This seems to be due to local extra thickness of copper & soldermask on the backside of the PCB which affects the micromegas amplification gap after DLC foil pressing.



ERAM detector      ERAM stiffener

ERAM-10 & 13: low gain pads are due to data analysis artefacts



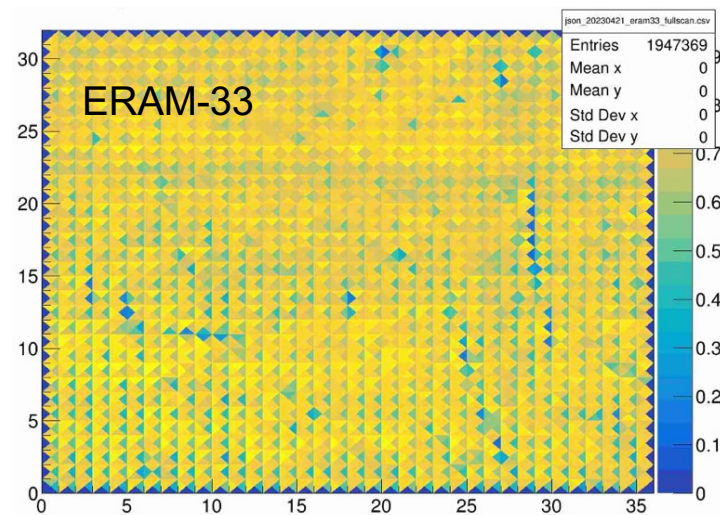
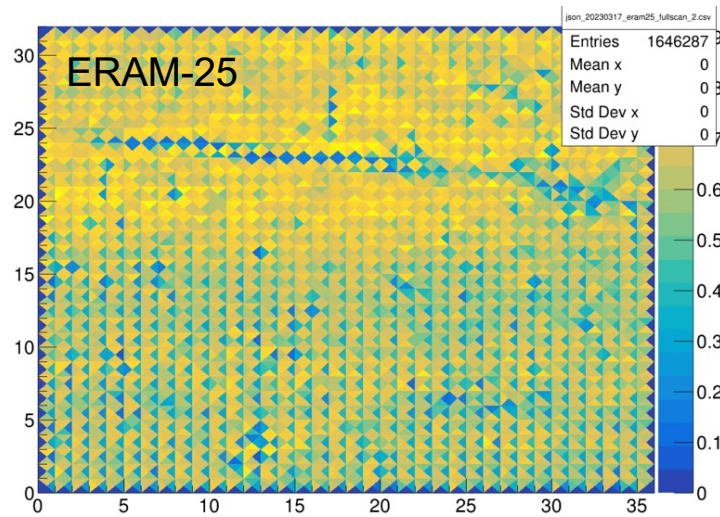


# ISSUES WITH BATCH 7 OF DLC FOILS

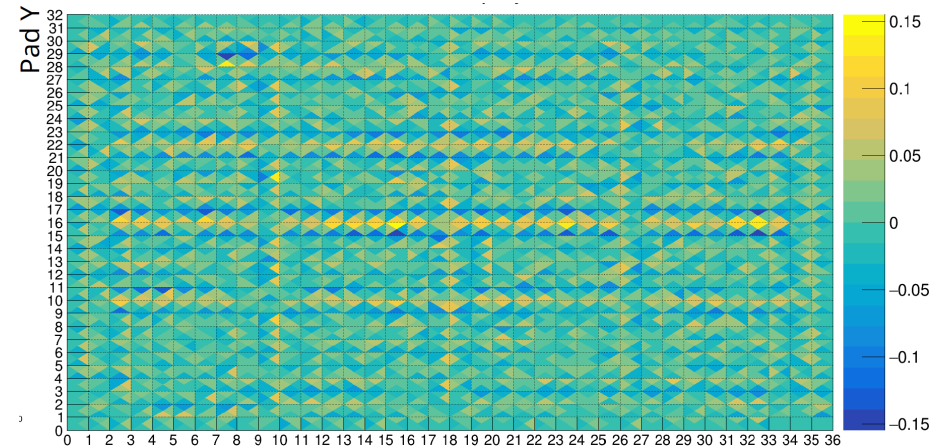
## CHARGE SPREADING MAPS

Ref: D. Henaff (CEA/Irfu)

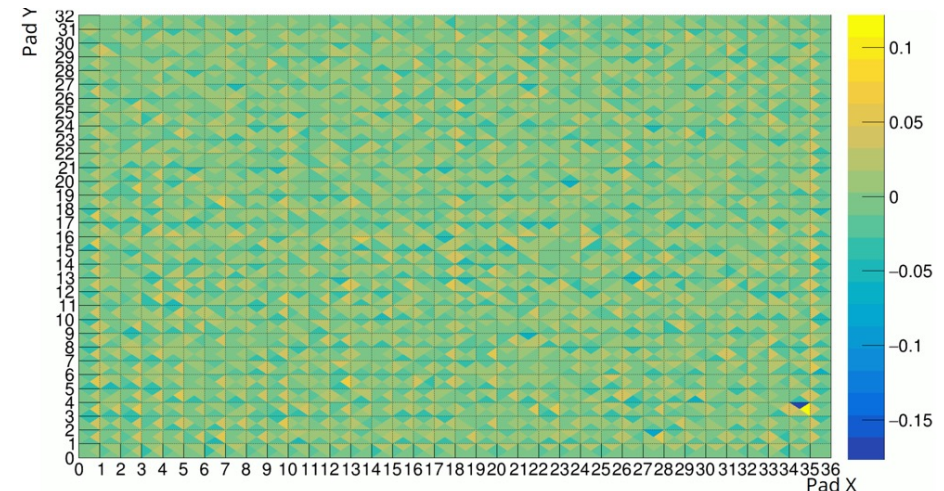
Charge sharing maps extracted from X-ray scan pad waveforms



An ERAM **before** PCB backside layer modification



A « good » ERAM (after S/N 23)

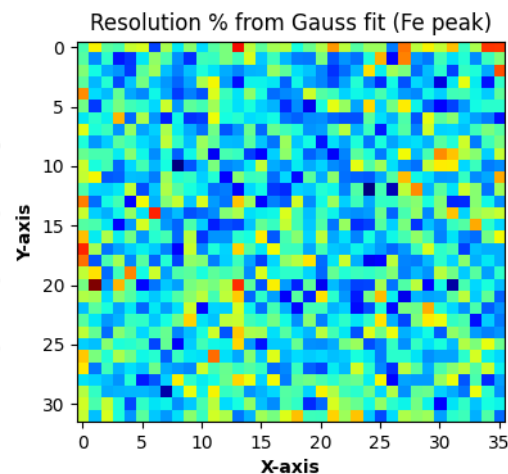
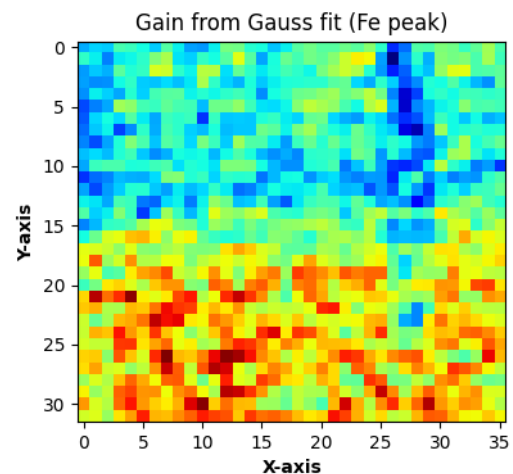


These defects may be correlated with DLC layer defects ... possibly because of too many baking treatments of the DLC foils

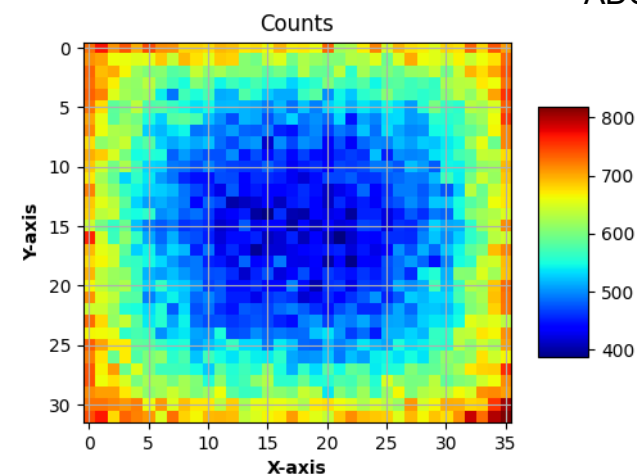
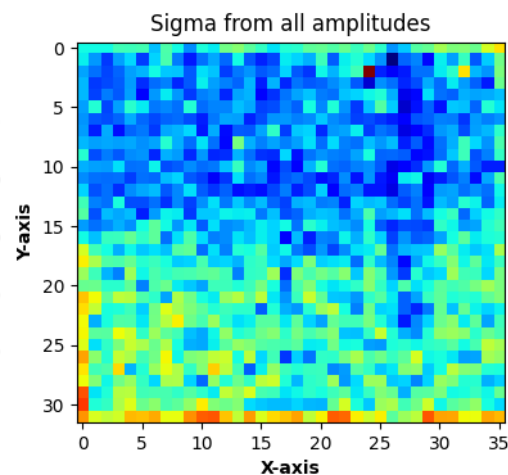
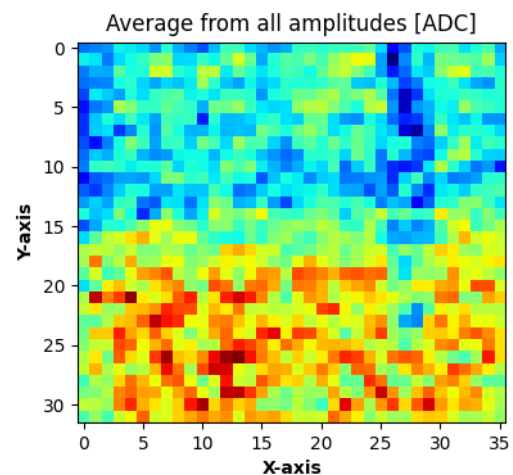
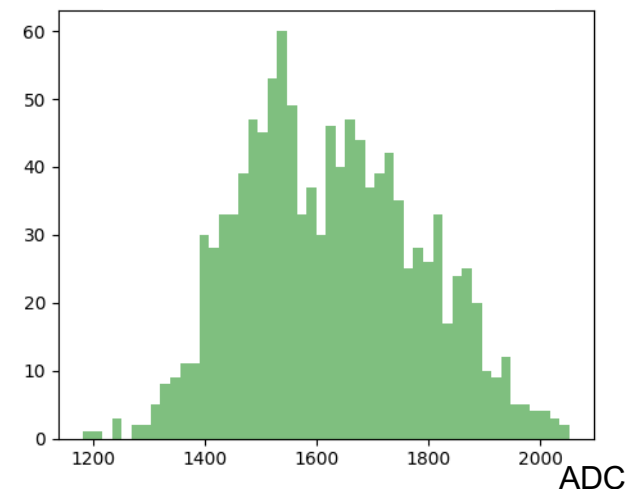


# ISSUES WITH BATCH 7 OF DLC FOILS GAIN GRADIENT ON ERAM-25, 33, 34

Tester name: Laura, ERAM ID: ERAM33, Date: 2023-04-21 23:01:16  
Source: Fe55, Comments: Full scan of ERAM33  
Ampl peak\_thr: 50, Ampl. calc with neighbours: True  
Scanned: 1152/1152, total time: 63.95 h



Histogram of mean amplitude



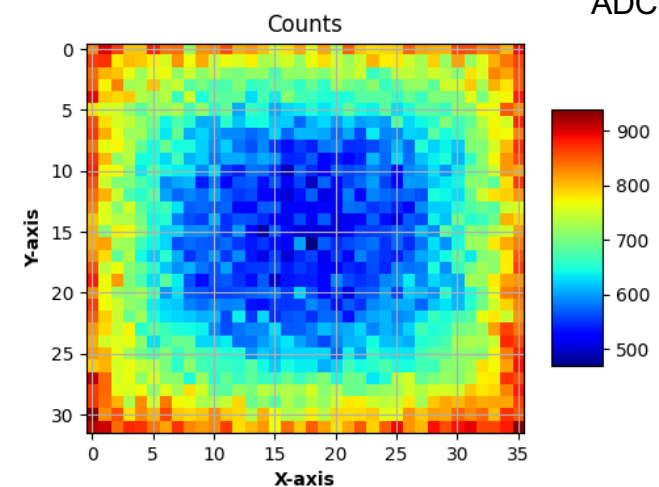
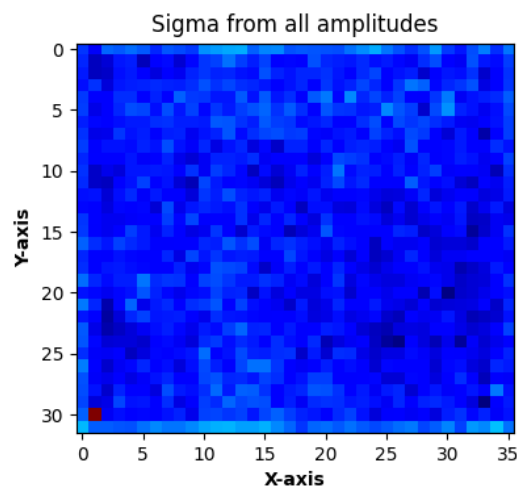
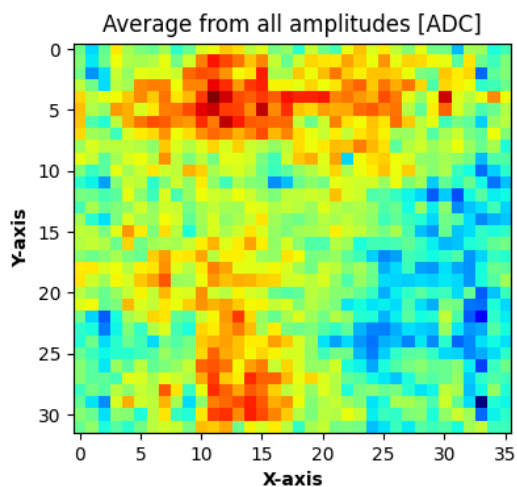
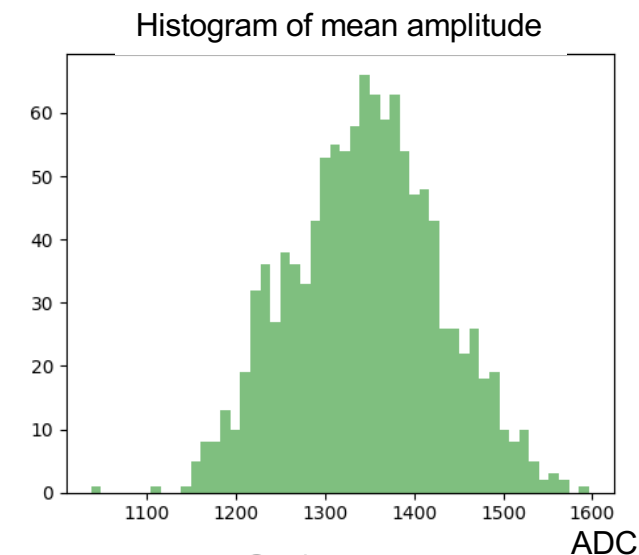
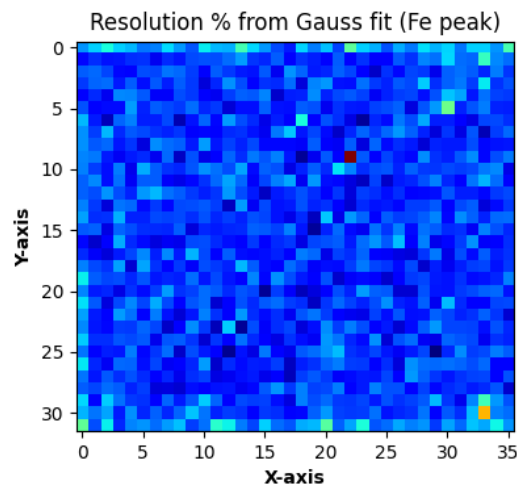
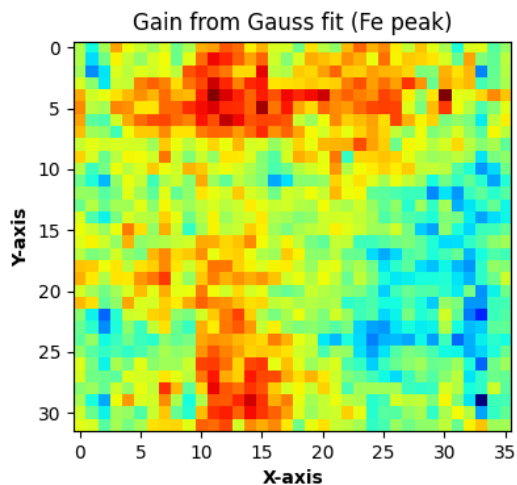
Problem at DLC pressing or mesh integration steps, not fully understood





# AN EXAMPLE OF A $^{55}\text{Fe}$ X-RAY SCAN OF A “TYPICAL” ERAM

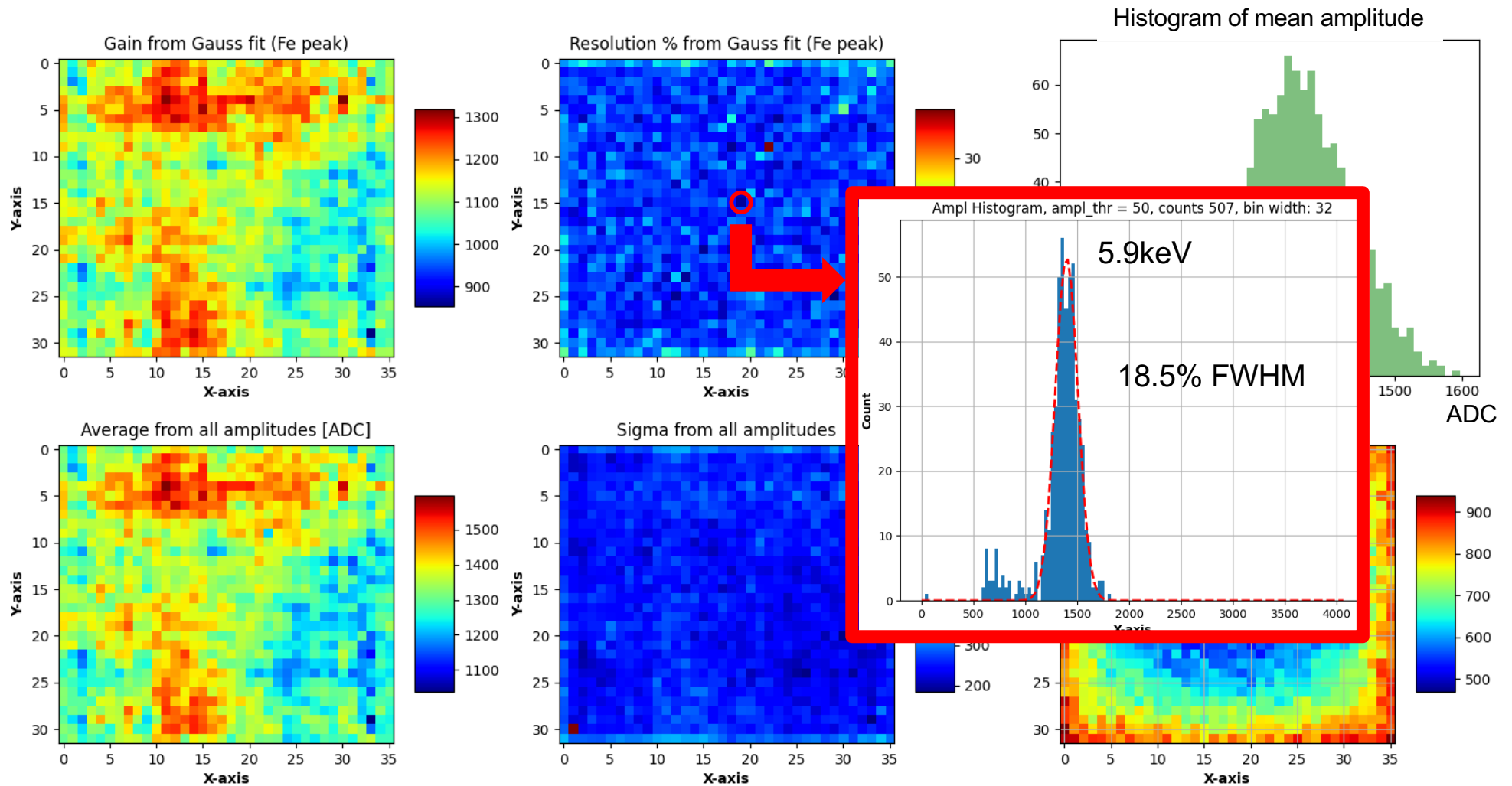
Tester name: Sara, ERAM ID: ERAM30, Date: 2022-07-22 08:47:59  
Source: Fe55, Comments: full scan with coordinates from cross-scan 412ns shaping time and 180s run time  
Ampl peak\_thr: 50, Ampl. calc with neighbours: True  
Scanned: 1152/1152, total time: 65.29 h



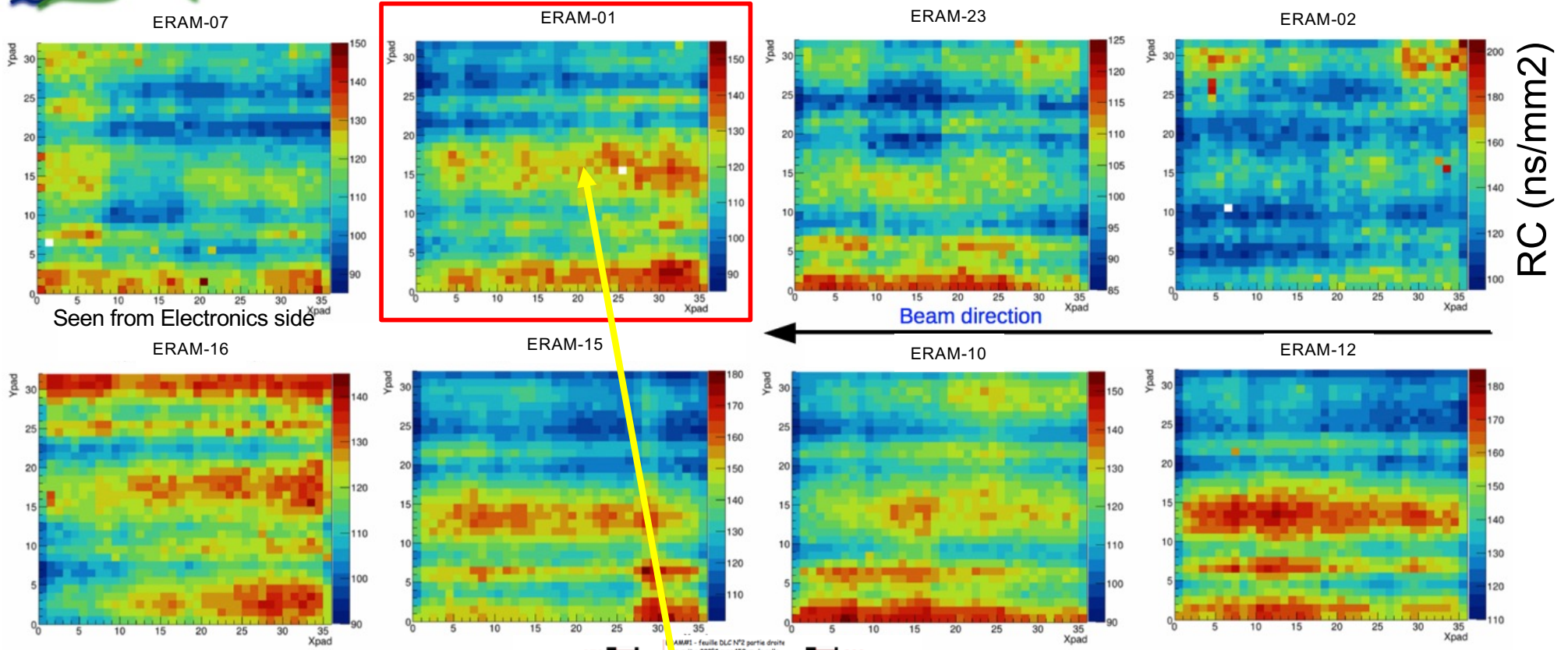


# AN EXAMPLE OF A $^{55}\text{Fe}$ X-RAY SCAN ERAM-30

Tester name: Sara, ERAM ID: ERAM30, Date: 2022-07-22 08:47:59  
Source: Fe55, Comments: full scan with coordinates from cross-scan 412ns shaping time and 180s run time  
Ampl peak\_thr: 50, Ampl. calc with neighbours: True  
Scanned: 1152/1152, total time: 65.29 h

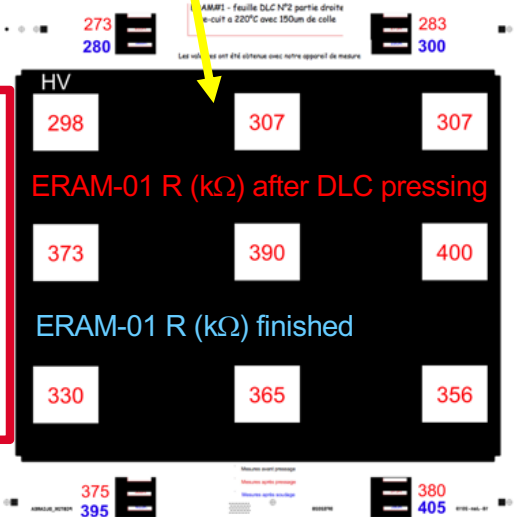






**Detailed model of pad signals**

- Primary electrons diffusion in gas and amplification in micromegas
- Charge amplifier response
- Charge dispersion on the DLC resistive anode Vs RC



ERAM	RC <sub>mean</sub> (ns/mm <sup>2</sup> )	Gain <sub>mean</sub>	
01	116.9	1944	
02	128.6	1736	
03	116.4	1987	
07	111.8	1898	
10	120.9	1697	
12	145.4	1635	
15	135.1	1629	
16	120.4	1705	
18	68.98	1277	~1/2 RC as expected
23	101.6	1393	
29	102	1318	~ RC as expected
30	114.3	1161	

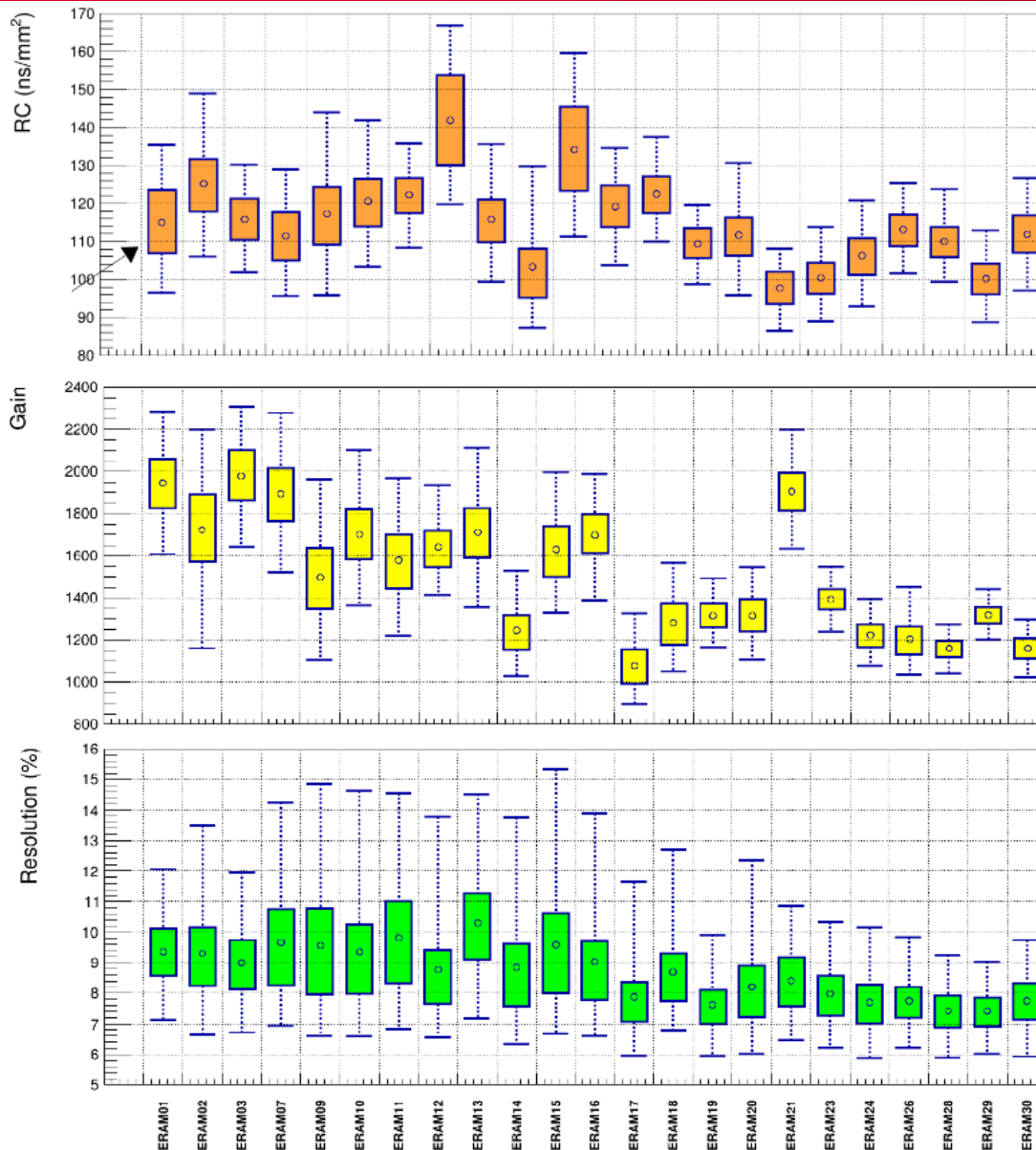
RC is quite well correlated to the measured DLC resistivity



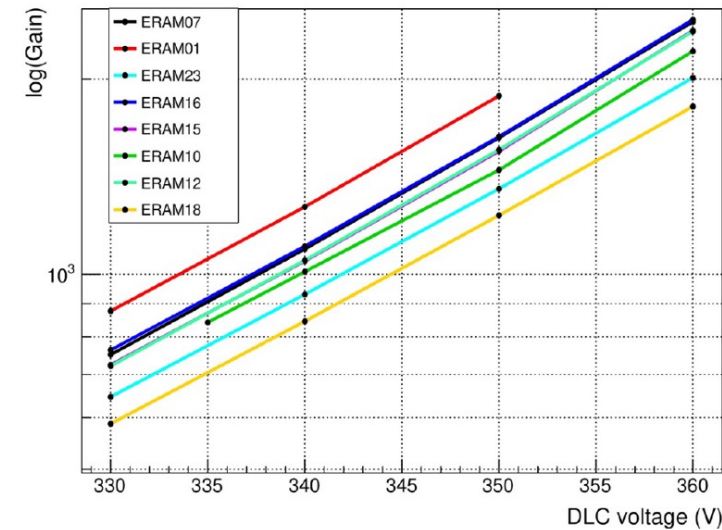
# STATUS OF ERAM PRODUCTION (06/23)

## TO BE COMPLETED WITH THE LAST ERAM SCANS

ref: D. Attié et al, Nucl.Instrum.Meth.A 1056 (nov 2023)  
Doi: 168534



Gain v/s DLC voltage



All ERAM with :  $0.38 < R_{meas} < 0.56 \text{ M}\Omega/\text{sq.}$   
C fixed by 150  $\mu\text{m}$  glue thickness

- |        |        |        |
|--------|--------|--------|
| ERAM01 | ERAM13 | ERAM21 |
| ERAM02 | ERAM14 | ERAM23 |
| ERAM03 | ERAM15 | ERAM24 |
| ERAM07 | ERAM16 | ERAM26 |
| ERAM09 | ERAM17 | ERAM28 |
| ERAM10 | ERAM18 | ERAM29 |
| ERAM11 | ERAM19 | ERAM30 |
| ERAM12 | ERAM20 |        |

**Except**  
ERAM-18 :  $\sim 1/2 R$   
( $1/2 RC$ )  
  
ERAM-29 :  $\sim 1/2 R$   
 $1/2$  Glue thickness  
same RC



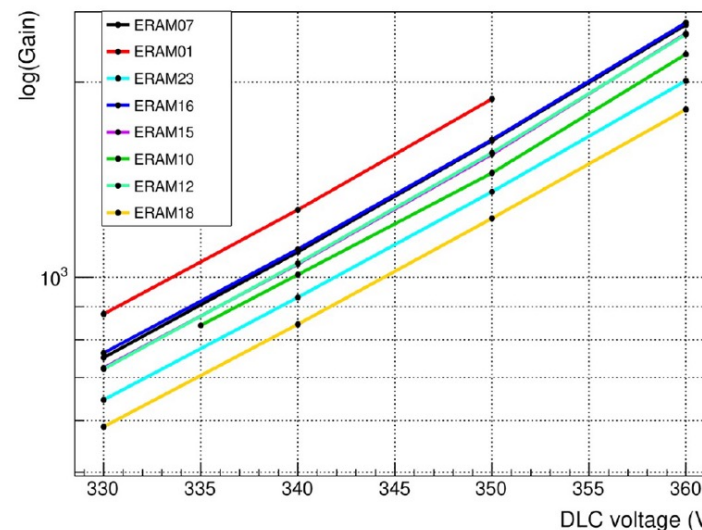


# STATUS OF ERAM PRODUCTION (06/23)

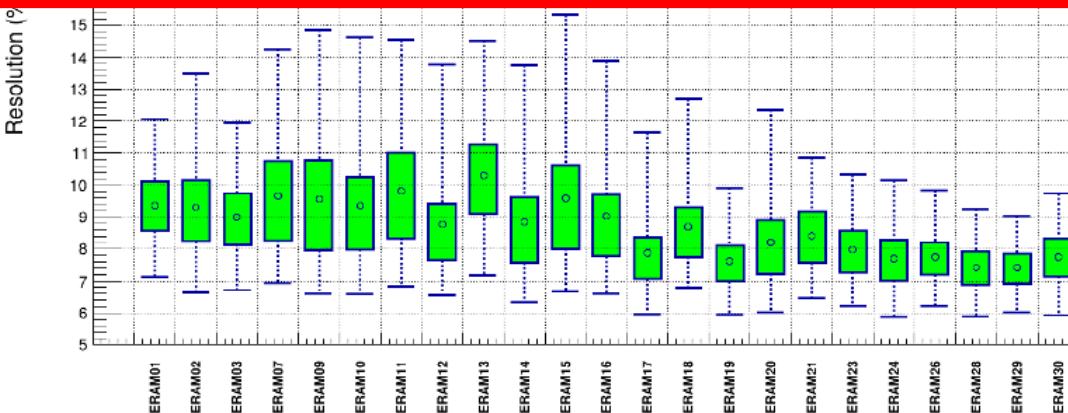
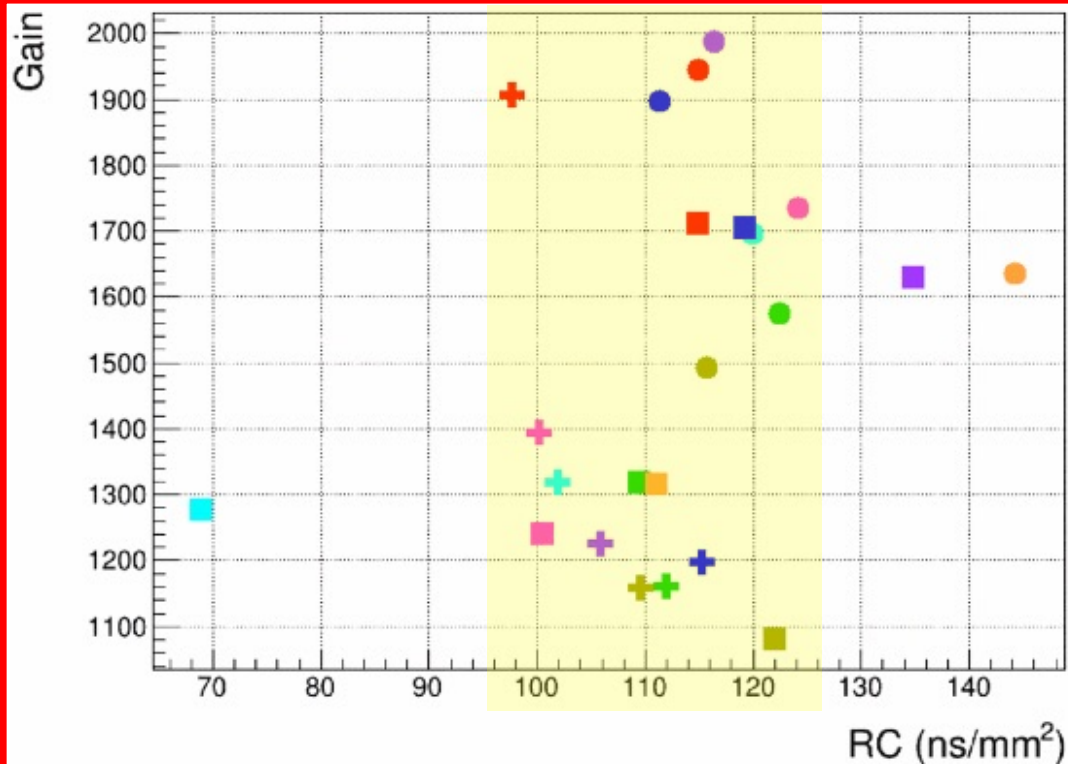
## TO BE COMPLETED WITH THE LAST ERAM SCANS

ref: D. Attié et al, Nucl.Instrum.Meth.A 1056 (nov 2023)  
Doi: 168534

Gain v/s DLC voltage



All ERAM with :  $0.38 < R_{meas} < 0.56 \text{ M}\Omega/\text{sq.}$   
C fixed by 150  $\mu\text{m}$  glue thickness



- |          |          |          |
|----------|----------|----------|
| ● ERAM01 | ■ ERAM13 | + ERAM21 |
| ● ERAM02 | ■ ERAM14 | + ERAM23 |
| ● ERAM03 | ■ ERAM15 | + ERAM24 |
| ● ERAM07 | ■ ERAM16 | + ERAM26 |
| ● ERAM09 | ■ ERAM17 | + ERAM28 |
| ● ERAM10 | ■ ERAM18 | + ERAM29 |
| ● ERAM11 | ■ ERAM19 | + ERAM30 |
| ● ERAM12 | ■ ERAM20 |          |

**Except**

ERAM-18 :  $\sim 1/2 R$   
( $1/2 RC$ )

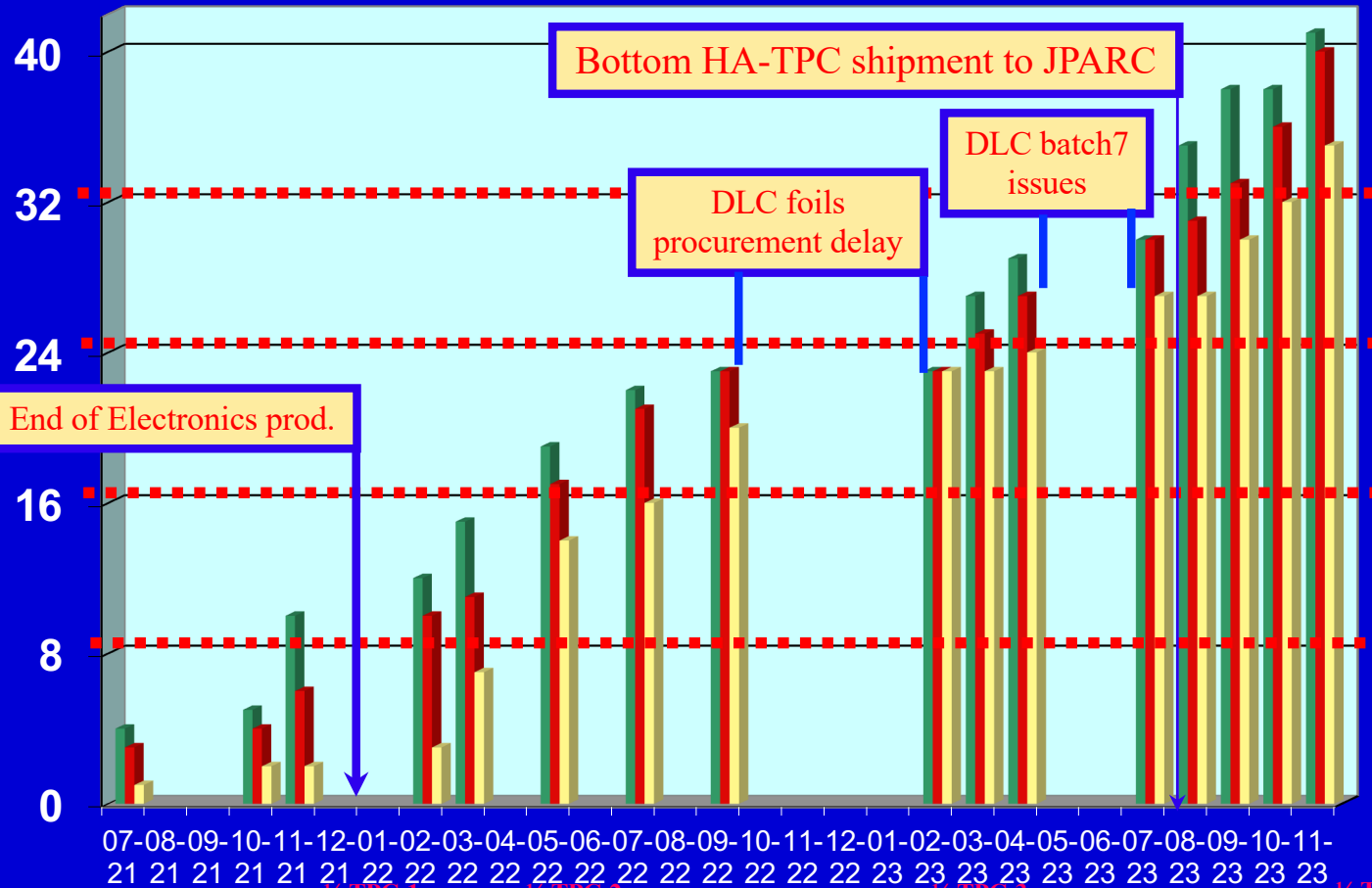
ERAM-29 :  $\sim 1/2 R$   
 $1/2$  Glue thickness  
same RC



# ERAM PRODUCTION SUMMARY

Number of ERAM modules

TPC TOP  
 1/2 TPC TOP  
 TPC BOTTOM  
 1/2 TPC BOTTOM



	07-21	10-21	11-21	02-22	03-22	05-22	07-22	09-22	02-23	03-23	04-23	07-23	08-23	09-23	10-23	11-23
ERAM detectors	4	5	10	12	15	19	22	23	23	27	29	30	35	38	38	41
ERAM modules	3	4	6	10	11	17	21	23	23	25	27	30	31	33	36	40
Validated ERAM modules	1	2	2	3	7	14	16	20	23	23	24	27	27	30	32	35

Number of ERAM validated at each step of the production (11/23)					
Total nb of PCB	QC0 (PCB)	QC1 (bulk-MM)	QC2 (mesh-pulsing)	QC3 (x-ray scan)	For HA-TPC
48	45	41	36 recovered to 41	35	33

+3 last QC3 in dec 23





# CONCLUSION AND PERSPECTIVES

- The T2K/HA-TPC ERAM detector module was designed to be a compact  $34 \times 42 \times 4 \text{ cm}^3$  unit suitable to pave large readout endcaps of TPCs.
- The production is finished with a total of 36 detectors qualified for use in the two HA-TPCs. A lot was learnt from this 2 years production and difficulties were overcome for an overall very good quality of the detectors : less than 1/1000 “dead” pads and no major issues to operate the detectors.
- The detector response modelization is consolidated and the performances of the detectors, driven by the RC constant of the charge spreading DLC stack, are within the specifications for the readout of the ND280/HA-TPCs.
- The use of the bottom HA-TPC in the T2K ND280 detector just began and its commissioning is on-going smoothly.
- The TOP HA-TPC will be equipped with its 16 ERAMs in February next year for an installation of the TPC in the basket of ND280 in April, finalizing the upgrade of the Near detector of T2K.